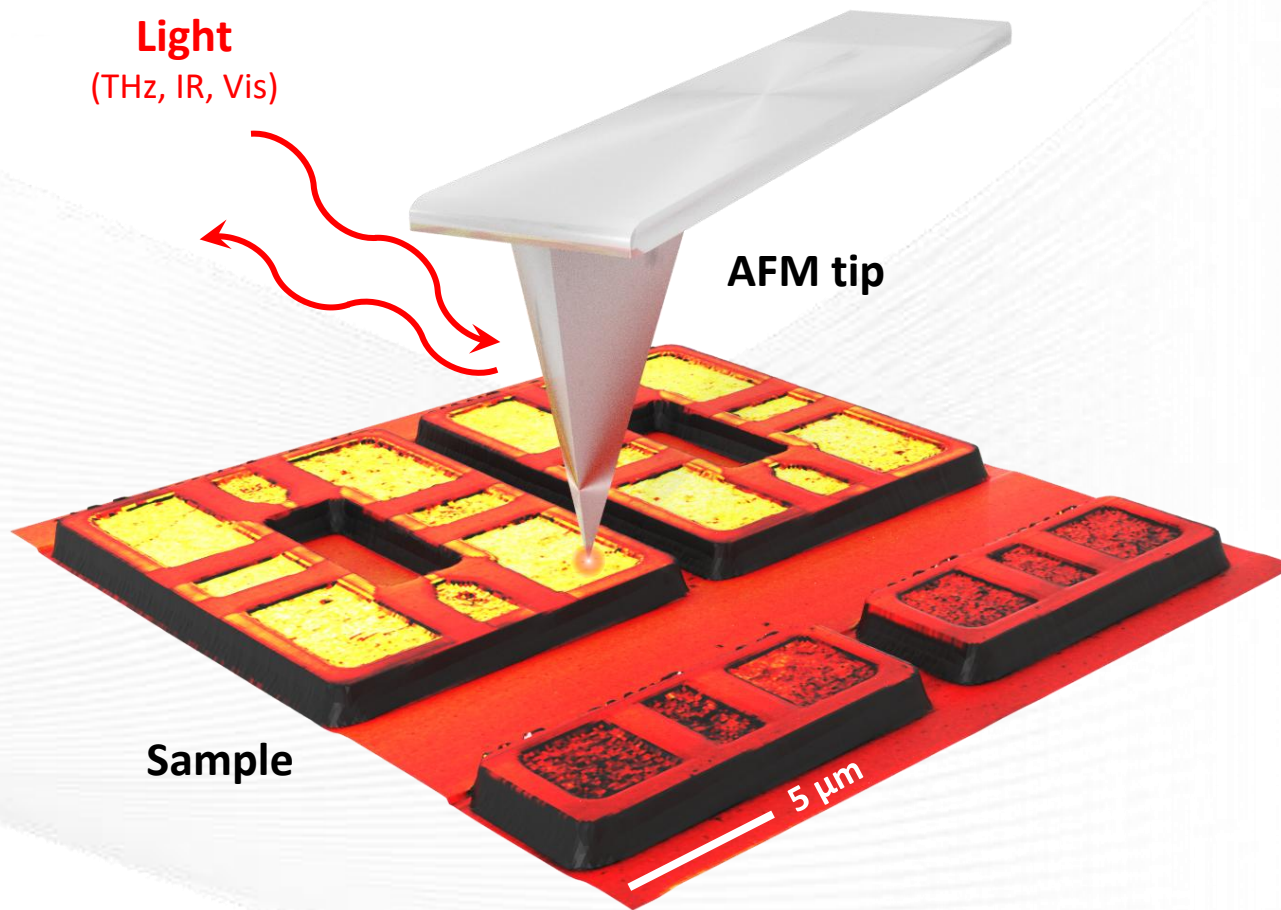


Nano-optical imaging and spectroscopy – An overview



1

Nano-IR probing principle(s)

AFM-IR / nano-FTIR

2

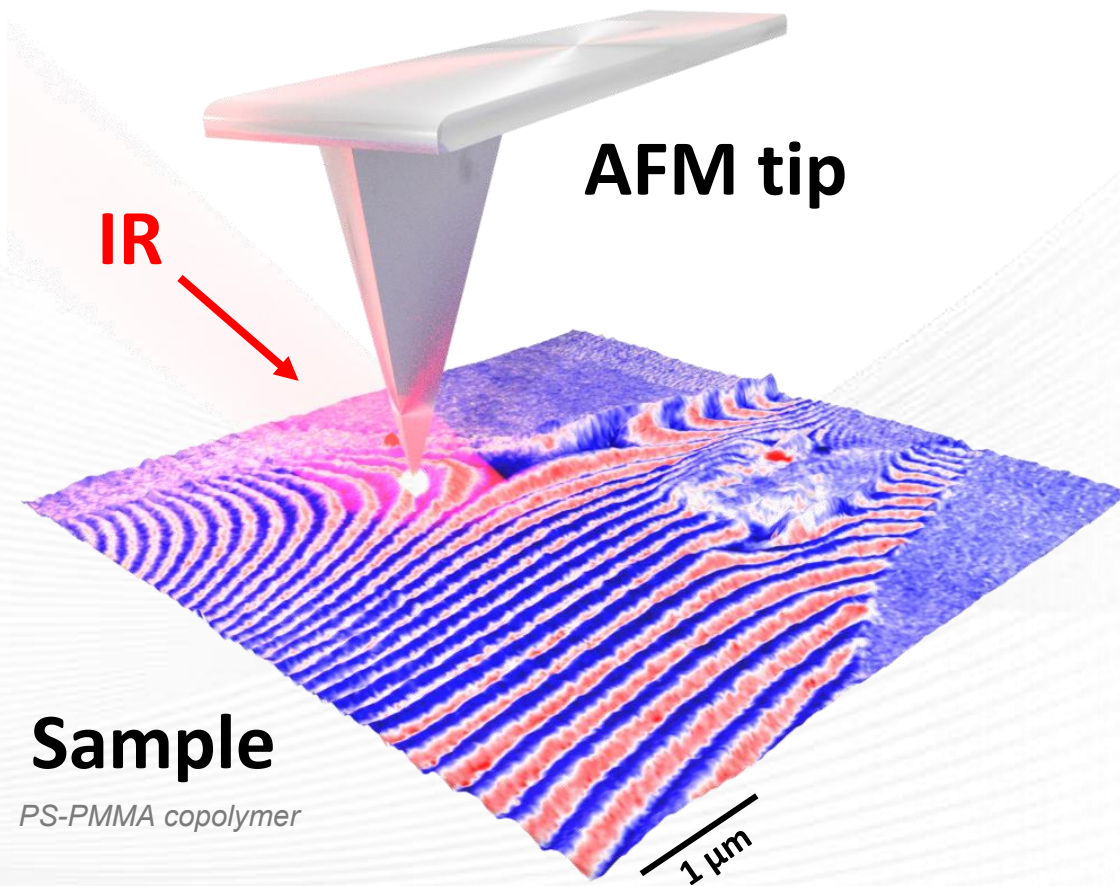
Application to Semicon Materials

Organic / Inorganic / Charge carriers

3

Not covered today

2D materials / photonics



IR spectroscopy + Atomic Force Microscopy

- ✕ Based on atomic force microscopy (AFM) technology
- ✕ Focused laser-beam illuminates metal AFM tip
- ✕ Concentrated optical hot spot below the tip apex
- ✕ **nano-IR absorption** is measured via
 - Photo-thermal force detection (**AFM-IR**, **PiFM**)
 - All-optical light detection (**nano-FTIR**, **s-SNOM**)
- ✕ Imaging & spectroscopy by sample scanning



Infrared imaging and spectroscopy
at ca. 10 nm spatial resolution

- B. Knoll, F. Keilmann, *Nature* **399**, 134 (1999)
- R. Hillenbrand et al., *Nat. Rev. Mat.* **10**, 285 (2025)



neaSNOM

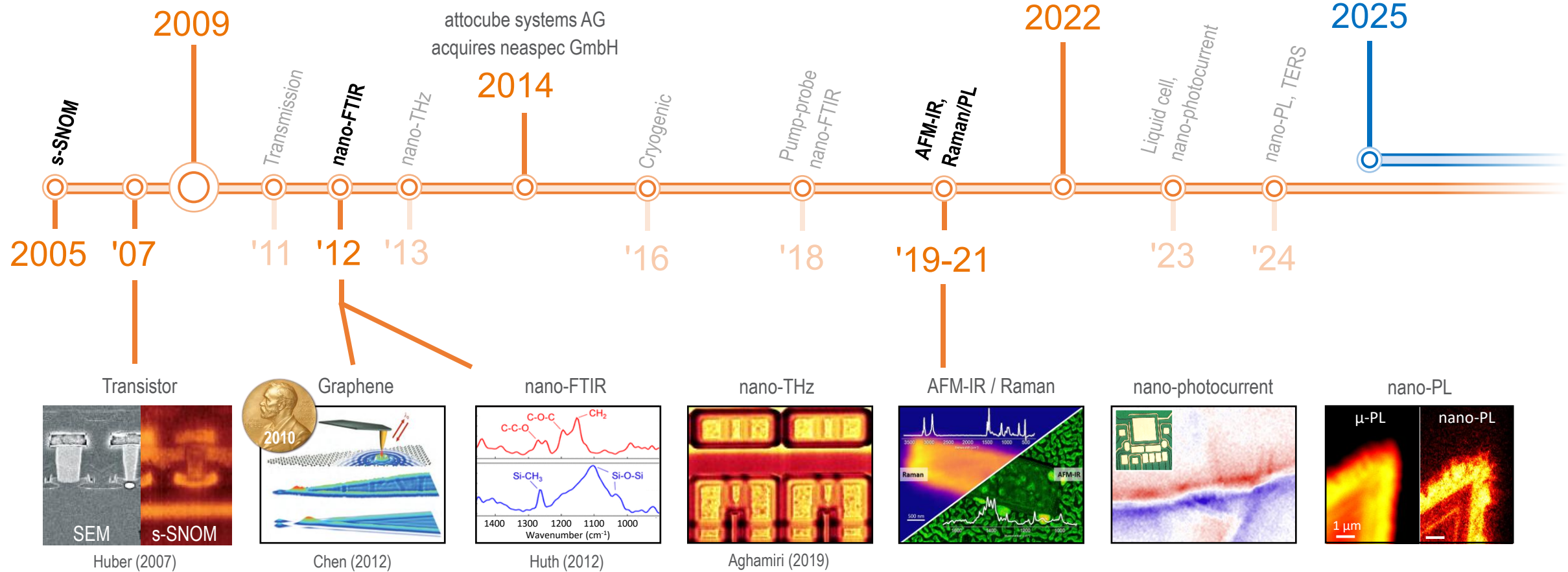
platform for near-field microscopy

neaSCOPE

microscopes for nanoscale analytics

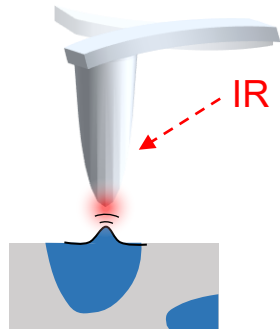
IRa-SCOPE

new era in vibrational spectroscopy



Silicon SiN SiO_x SiC, GaN InP	List of publications for semiconducting materials Quantification of carrier density gradients along axially doped silicon nanowires using infrared nanoscopy, Jung et al, <i>ACS Photonics</i> 6, 7, 1744-1754 (2019) Hyperspectral time-domain terahertz nanoimaging, Aghamiri et al, <i>Optics Expr.</i> 27, 24231 (2019) All-electronic terahertz nanoscopy, Liewald et al, <i>Optica</i> 5, 2, 159-163 (2018) Mapping Free-Carriers in Multijunction Silicon Nanowires Using Infrared Near-Field Optical Microscopy, Ritchie et al, <i>Nano Lett.</i> 17, 11, 6591-6597 (2017) Terahertz Near-Field Nanoscopy of Mobile Carriers in Single Semiconductor Nanodevices, Huber et al, <i>Nano Lett.</i> 8, 11, 3766-3770 (2008) Simultaneous IR Material Recognition and Conductivity Mapping by Nanoscale Near-Field Microscopy, Huber et al., <i>Adv. Mater.</i> 19, 2209 (2007) Near-field infrared spectroscopy of SiO_x nanowires, Milekhin et al, <i>Appl Surf Sci</i> 584, 152583 (2022) Model for quantitative tip-enhanced spectroscopy and the extraction of nanoscale-resolved optical constants, McLeod et al, <i>Physical Review B</i>, 90, 085136 (2014) Nanoscale Infrared Spectroscopic Characterization of Extended Defects in 4H-Silicon Carbide, Criswell et al, <i>Nano Lett.</i> 24, 1, 114-121 (2024) Near-field imaging and spectroscopy of locally strained GaN using an IR broadband laser, Bensmann et al., <i>Opt. Expr.</i> 22, 19, 22369 (2014) Nanoscale residual stress-field mapping around nanoindentations in SiC by IR s-SNOM and confocal Raman microscopy, Huber et al, <i>Nature Nanotech</i> 4, 153 (2009) Nanoscale Resolved Infrared Probing of Crystal Structure and of Plasmon-Phonon Coupling, Huber et al, <i>Nano Lett.</i> 6, 774 (2006) Subwavelength-scale tailoring of surface phonon polaritons by focused ion-beam implantation, Ocelic et al, <i>Nature Materials</i> 3, 606 (2004) Nanoscale Free-Carrier Profiling of Individual Semiconductor Nanowires by Infrared Near-Field Nanoscopy, Stiegler et al, <i>Nano Lett.</i> 10, 1387 (2010) Ultrafast multi-terahertz nano-spectroscopy with sub-cycle temporal resolution, Eisele et al, <i>Nature Phot.</i> 8, 841-845 (2014) Ultrafast Dynamics of Surface Plasmons in InAs by Time-Resolved Infrared Nanospectroscopy, Wagner et al, <i>Nano Lett.</i> 14, 8, 4529-4534 (2014) Tunable Low Loss 1D Surface Plasmons in InAs Nanowires, Zhou et al, <i>Adv. Mat.</i> 30, 35, 1802551 (2018) Unveiling the detection dynamics of semiconductor nanowire photodetectors by terahertz near-field nanoscopy, Pogna et al, <i>Light Sci Appl</i> 9, 189 (2020) Phonon-Enhanced Near-Field Spectroscopy to Extract the Local Electronic Properties of Buried 2D Electron Systems in Oxide Heterostructures, Barnett et al, <i>Adv Mat</i> 30, 46, 2004767 (2020) High sensitivity variable-temperature infrared nanoscopy of conducting oxide interfaces, Luo et al, <i>Nature Comm</i> 10, 2774 (2019) Two-dimensional polyaniline crystal with metallic out-of-plane conductivity, Zhang et al, <i>Nature</i> 638, 411-417 (2025) Solvent-structured PEDOT:PSS surfaces: fabrication strategies and nanoscale properties, Sanviti et al, <i>Polymer</i> 246, 124723 (2022) Near-field infrared nanoscopic study of EUV- and e-beam-exposed hydrogen silsesquioxane photoresist, Kim et al, <i>Nano Convergence</i> 9, 53 (2022) Microdomain homogeneity evaluation of perpendicular lamellar structures in block copolymer films: X-ray scattering and IR nanospectroscopy analyses, Lee et al, <i>Polymer Testing</i> 104, 107409 (2021) Nano-FTIR Absorption Spectroscopy of Molecular Fingerprints at 20 nm Spatial Resolution, Huth et al, <i>Nano Lett.</i> 12, 8, 3973-3978 (2012) On-surface photopolymerization of two-dimensional polymers ordered on the mesoscale, Grossmann et al, <i>Nature Chemistry</i> 13, 730-736 (2021) Correlating gas permeability and morphology of bio-based polyether-block-amide copolymer membranes by IR nanospectroscopy, David et al, <i>J of Membrane Science</i> 708, 123001 (2024) Characteristic length scales of the electrically induced insulator-to-metal transition, Luibrand et al, <i>Phys. Rev. Research</i> 5, 013108 (2023) Characterization of semiconductor materials using synchrotron radiation-based near-field infrared microscopy and nano-FTIR spectroscopy, Hermann et al, <i>Optics Express</i>, 22, 17948 (2014) Mott Transition in VO₂ Revealed by Infrared Spectroscopy and Nano-Imaging, Qazilbash et al, <i>Science</i> 318, 5857 (2007)	InAs 2DEG Organic semicon. Photo-resist Contam. ID Others, inorganic
---	--	--

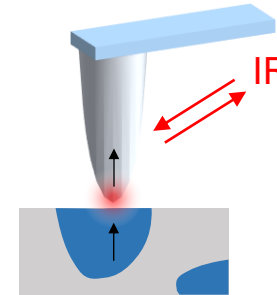
AFM-IR Force detection



Probing absorption $\kappa \sim \text{Im } \varepsilon$
(via photo-thermal expansion)

- ✔ Absorption
- ✔ Excels on organic materials
- ✔ Cheaper (less optics)
- ✔ Quantitative, relative

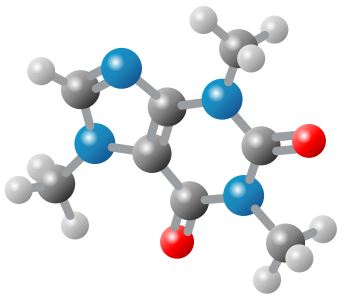
nano-FTIR Light detection



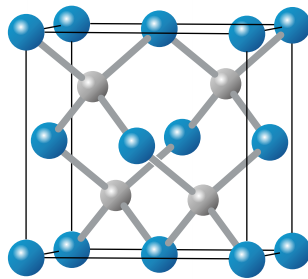
Probing permittivity ε
(via dipole-dipole interaction)

- ✔ Reflection & absorption
- ✔ Most Versatile (all materials)
- ✔ THz, Infrared, Visible light
- ✔ Quantitative, absolute

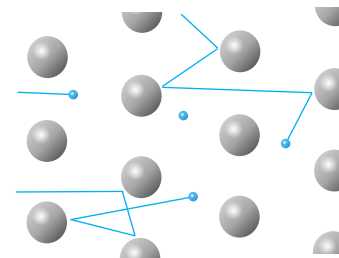
Molecular vibrations



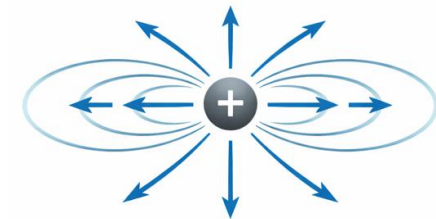
Lattice vibrations



Charge carriers

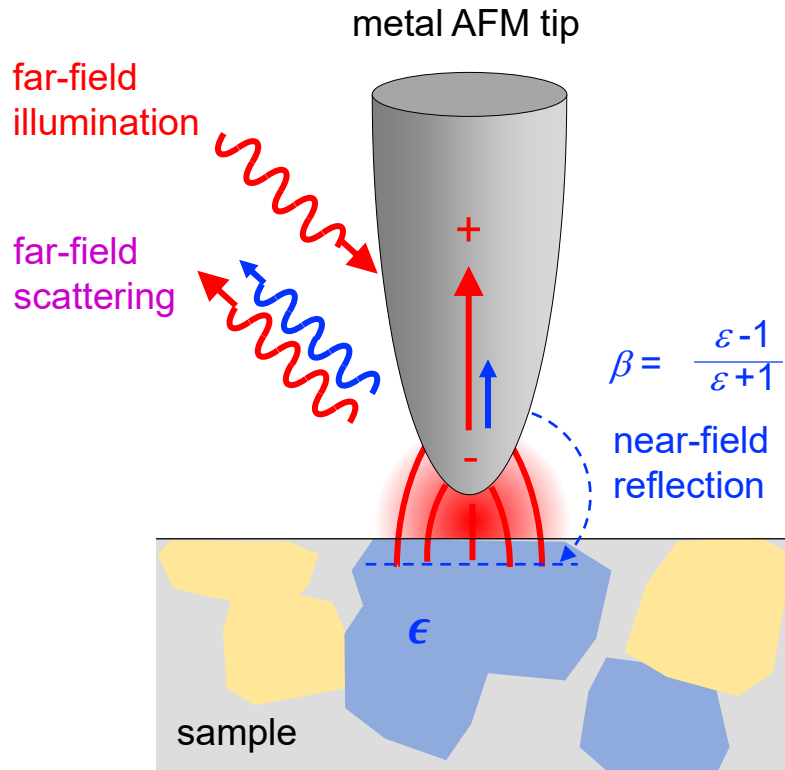


Electric near-fields



Probing mechanism in nano-IR

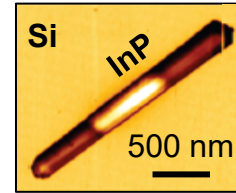
Spectroscopic information explains image contrasts



nano-FTIR essentially probes
sample permittivity ϵ , via $\beta(\epsilon)$

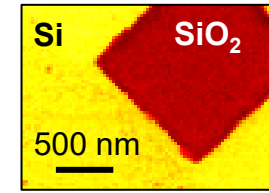
AFM-IR probes $\text{Im}(\epsilon)$

Charge
carriers



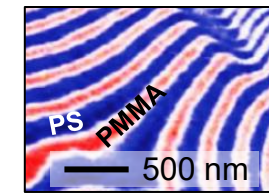
THz – Vis

Lattice
vibrations



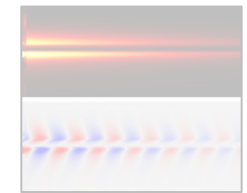
THz – mid-IR

Molecular
vibrations

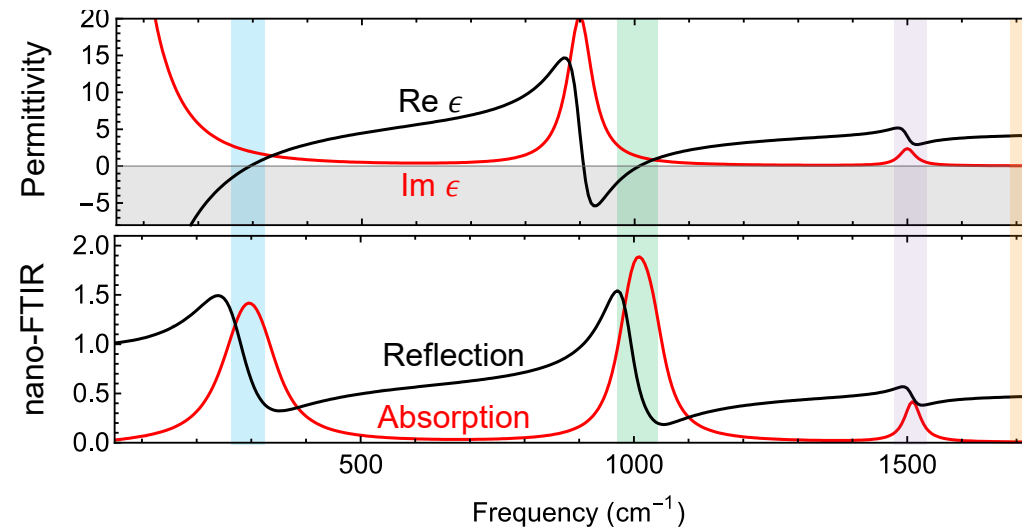


mid-IR

Electric
fields



mid-IR – NIR – Vis



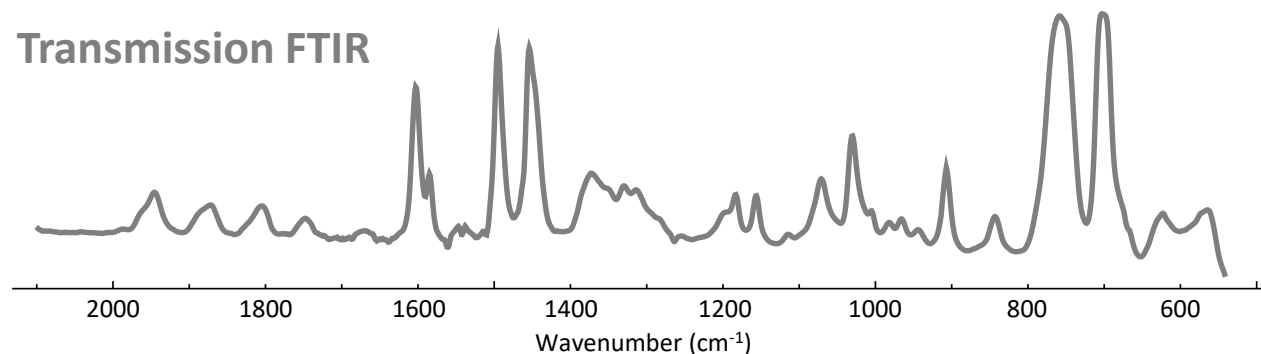
Recent review
Hillenbrand et al,
Nature Rev. Mat. **10**,
285-310 (2025)

$$\epsilon = \underbrace{\epsilon_{\infty}}_{\text{Dielectric constant}} \left(1 - \underbrace{\frac{\omega_p^2}{\omega^2 - i\omega\gamma_p}}_{\text{Drude model}} \right) + \underbrace{\frac{A_{ph}^2}{\omega_{ph}^2 - \omega^2 + i\omega\gamma_{ph}}}_{\text{Strong oscillator}} + \underbrace{\frac{A_m^2}{\omega_m^2 - \omega^2 + i\omega\gamma_m}}_{\text{Weak oscillator}}$$

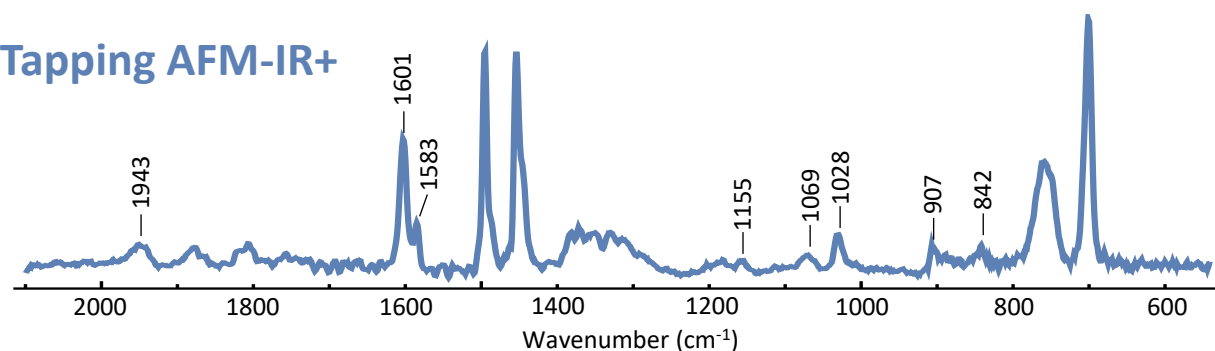
Chemical identification of nanoscale contaminants

Enabled by spectral match of FTIR and nano-IR data

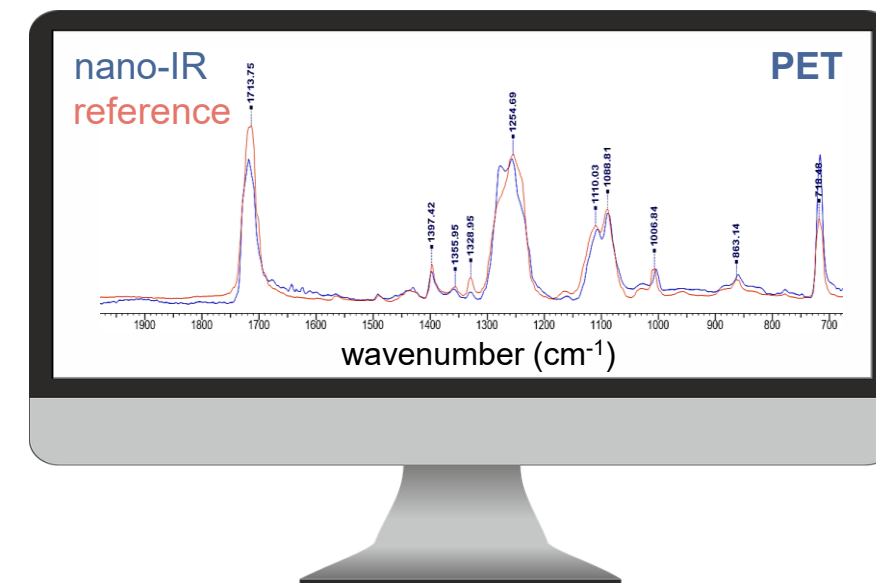
Transmission FTIR



Tapping AFM-IR+



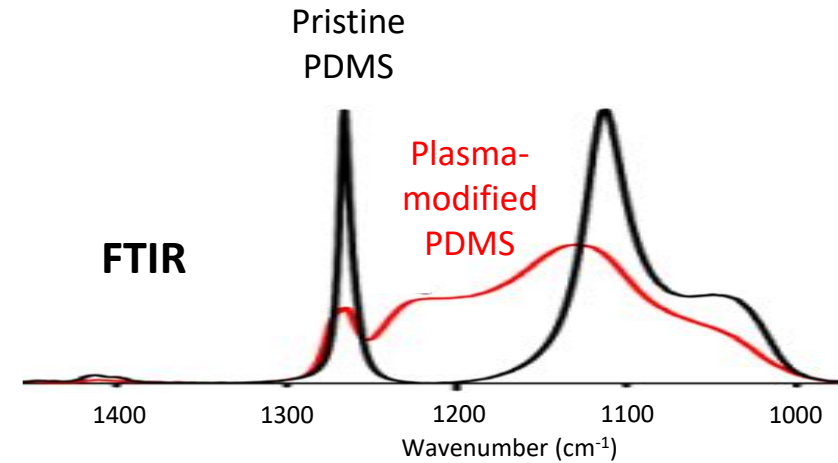
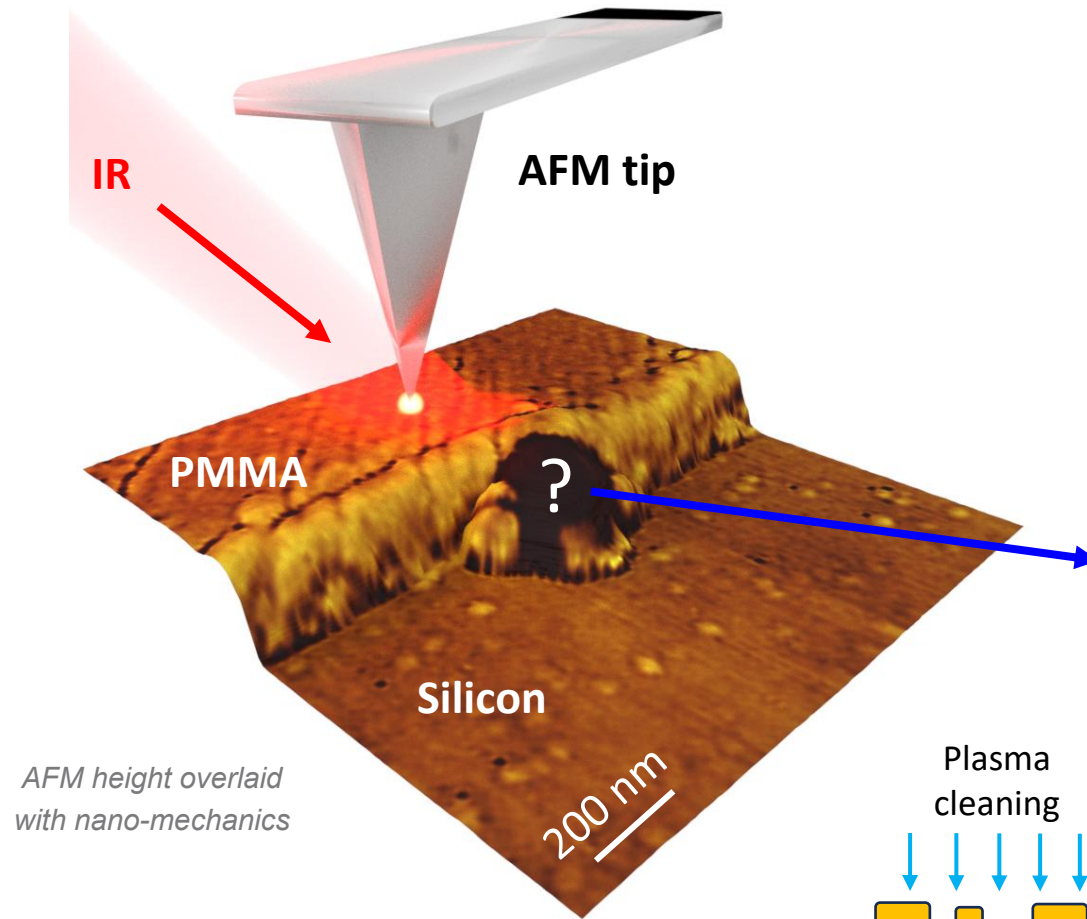
**Chemical nano-identification
based on established FTIR libraries**



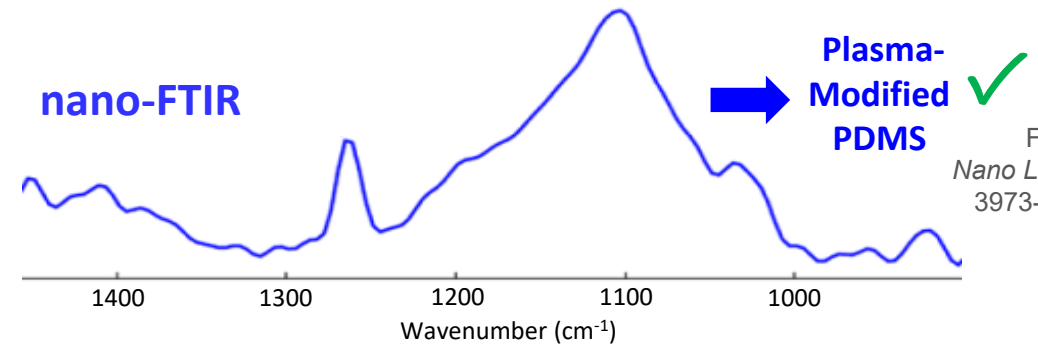
Hit rating		Material					
	Hit rating	Tag	Kor	DE	Kennz	Name	Spektrum <automatisch> (IR/ATR-IR)
1	83.61			HMX	<u>8440</u>	Poly(methyl methacrylate)	
2	83.59			HMX	<u>8377</u>	Poly(methyl methacrylate)s	
3	83.58			CRX	<u>543</u>	POLY(METHYL METHACRYLATE) (MW=33,000)	
4	83.58			BMX	<u>609</u>	POLY(METHYL METHACRYLATE)/n-BUTYL METHACRYLATE	

Beyond identification: Tracing the origin of nanoscale contaminants

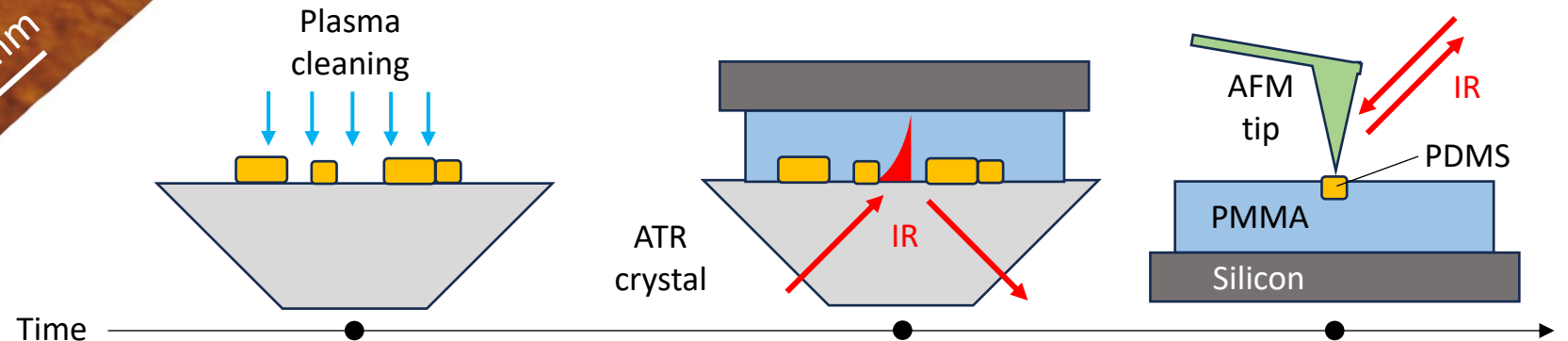
Enabled by spectral match of FTIR and nano-IR data



V. Danilov et al.,
Plasma Processes and Polymers, 8, 11 (2011)

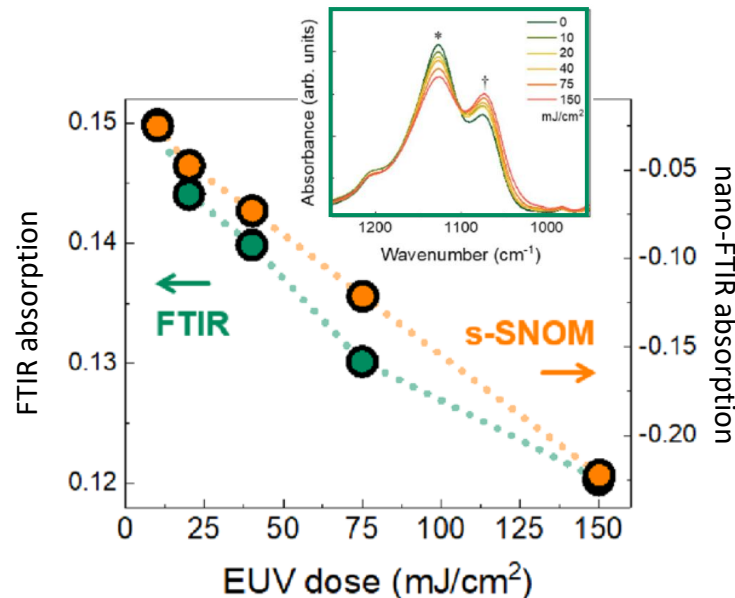
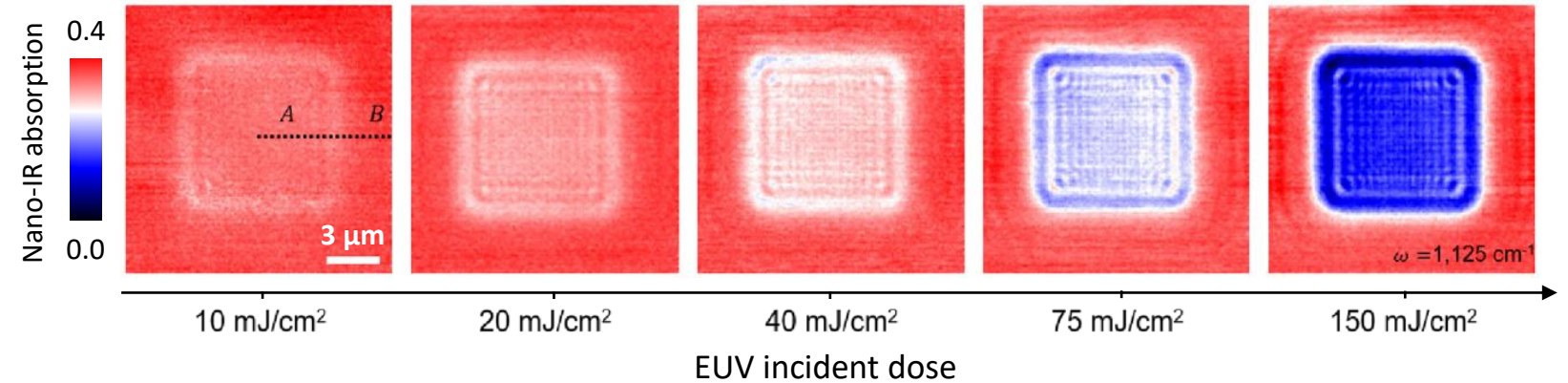
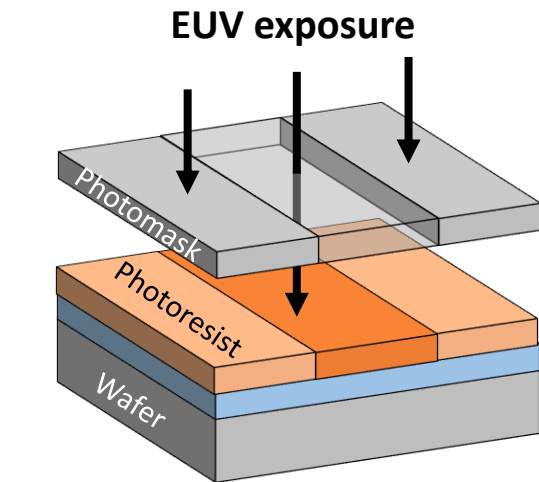


F. Huth et al.,
Nano Letters, 12, 8,
3973-3978 (2012)

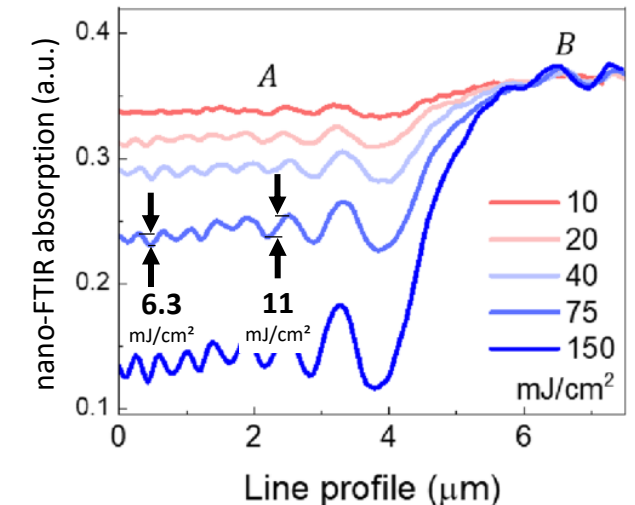


Lithography – probing local resist chemistry using nano-IR

Photoresist HSQ (hydrogen silsesquioxane)

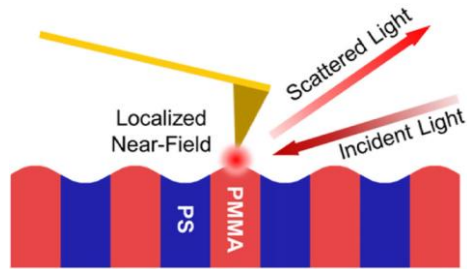


- **Change in cross-linking density** leads to nano-IR image contrast
- Local absorption contrast **scales linearly with EUV exposure dose** (analogous to FTIR in HSQ resist)
- Thus, image contrast can be interpreted and quantified as **local variations in EUV incident dose**

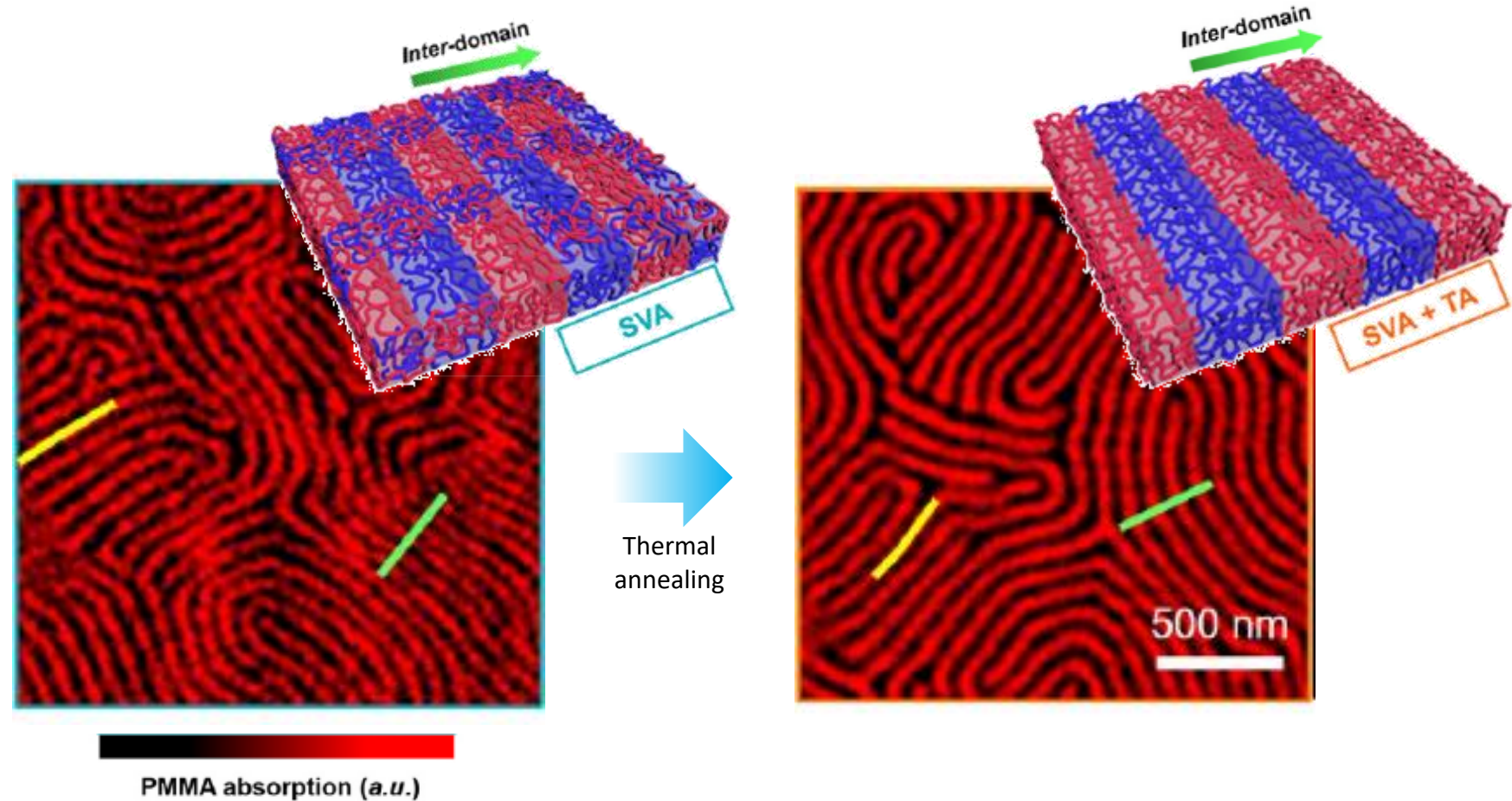


Optimizing photoresist & process steps with the help of nano-IR

Co-polymer PS-*b*-PMMA for directed self-assembly



- Significant **enhancement of Inter-domain chemical contrast** upon SVA + TA treatment (nano-FTIR 3.3x, GISAXS 4x)
- **Intra-domain uniformity increased** as confirmed by nano-FTIR absorption mapping

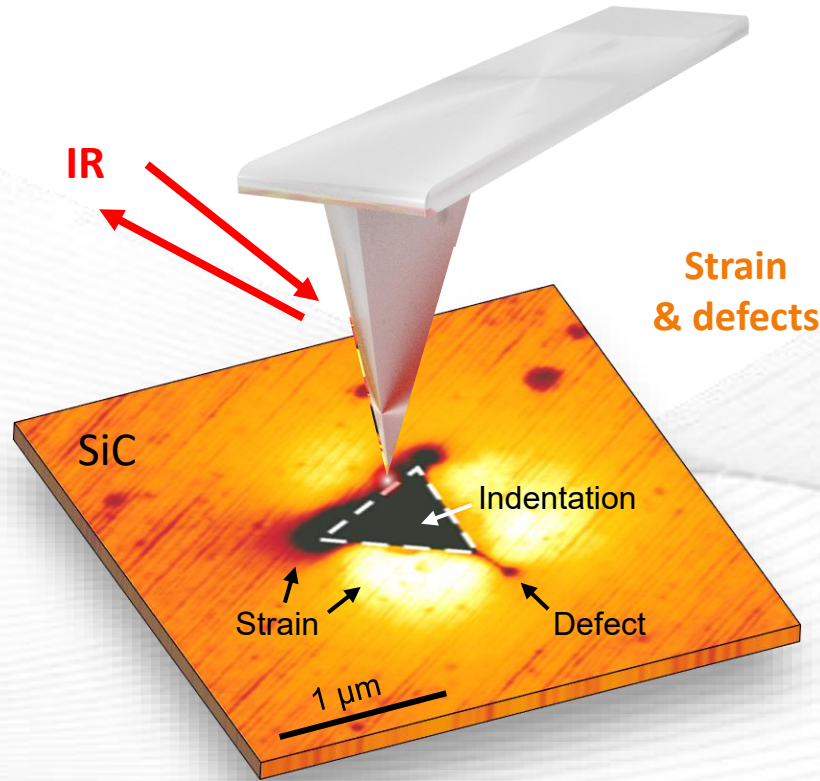


Chemical noise
Mapped by nano-FTIR

Increased chemical contrast
After thermal annealing

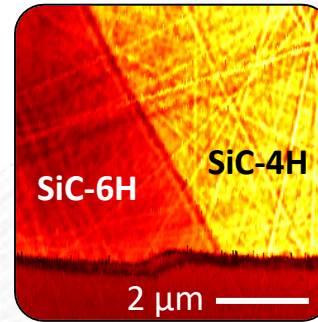
W. Lee, et al., *Polymer Testing* **104**, 104409 (2021)

J. Kim et al. *Spect. Act. A* **274**, 121095 (2022)



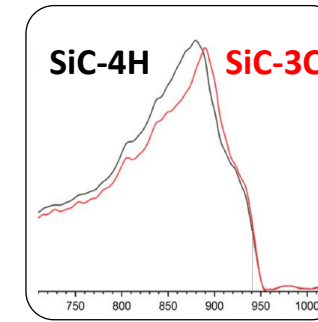
[A Huber \(2009\)](#)

Polytypes



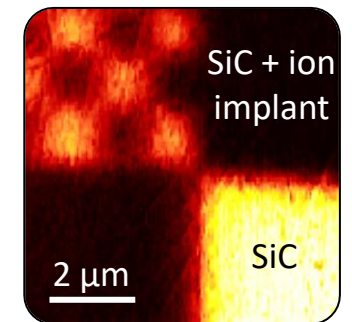
[Huber \(2006\)](#)

Stacking faults



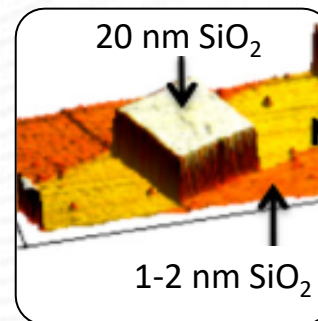
[Criswell \(2024\)](#)

Lattice damage



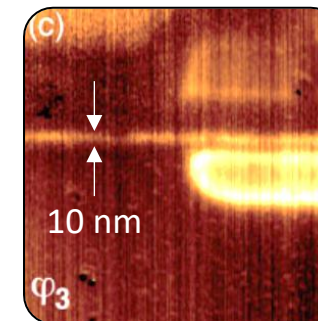
[Ocelic \(2004\)](#)

Oxides



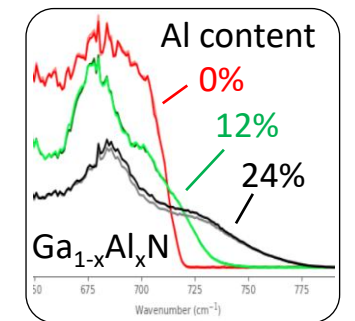
[L M Zhang \(2012\)](#)

Nitrides



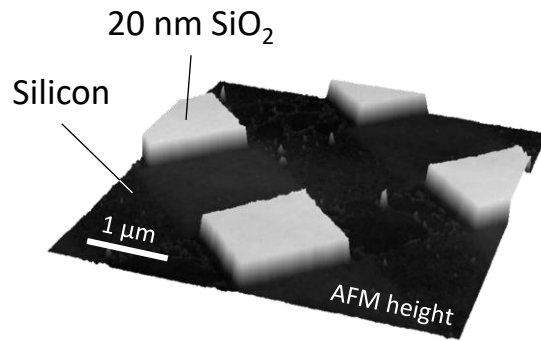
[A Huber \(2007\)](#)

Composition

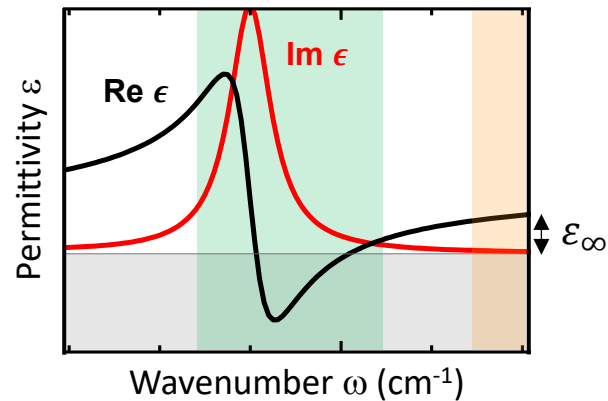


Probing mechanism in nano-IR – Lattice vibrations

Spectroscopic information explains image contrasts

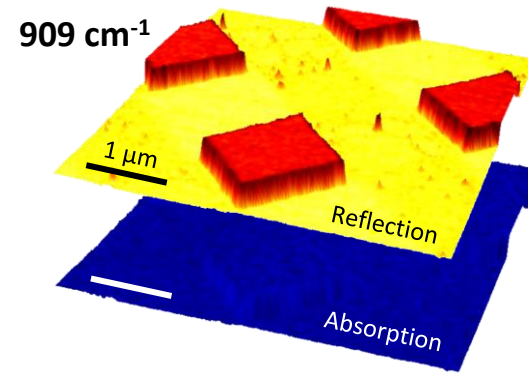


Optical properties
of lattice vibrations

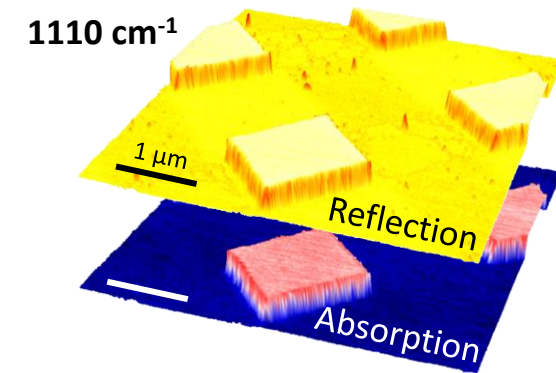
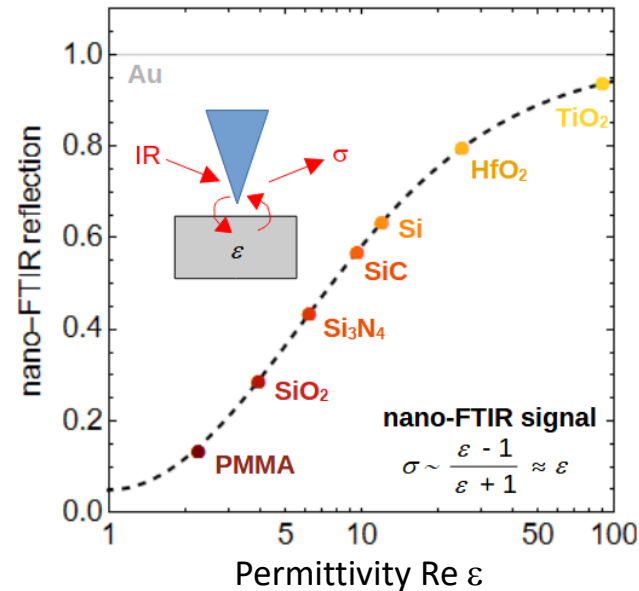


$$\epsilon = \frac{A_{ph}^2}{\omega_{ph}^2 - \omega^2 + i\omega\gamma_{ph}} + \epsilon_\infty$$

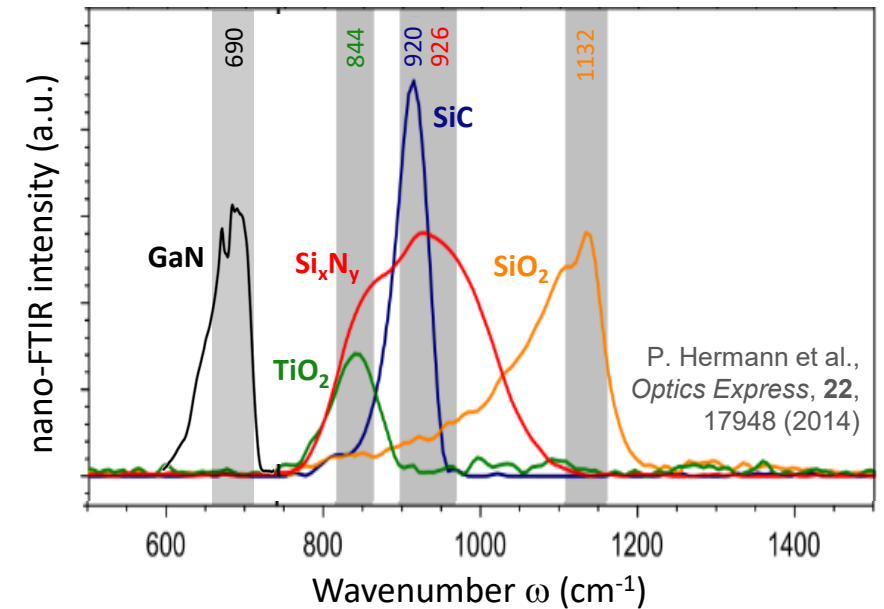
Strong oscillator Dielectric constant



Off-resonant
(non-absorbing)

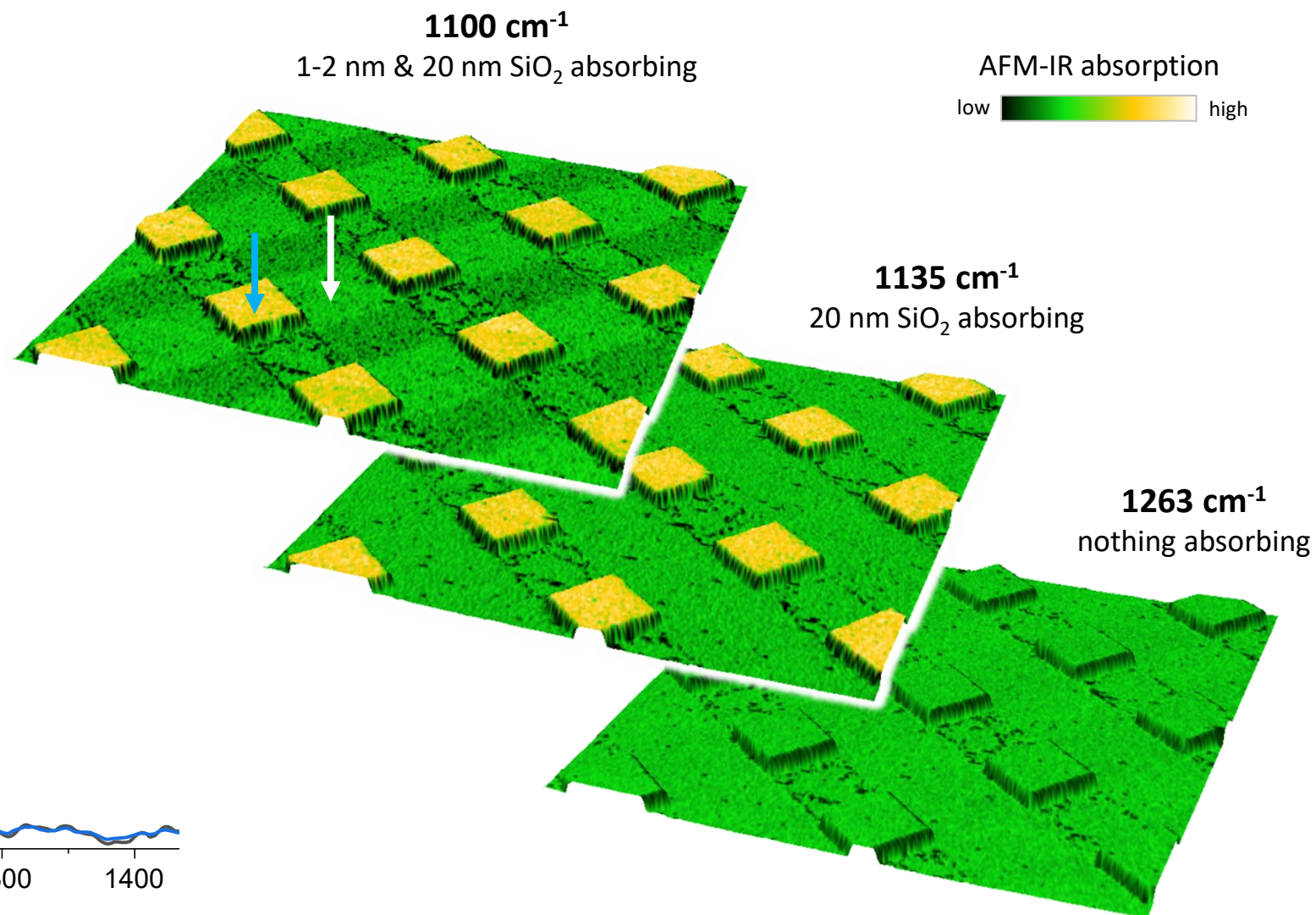
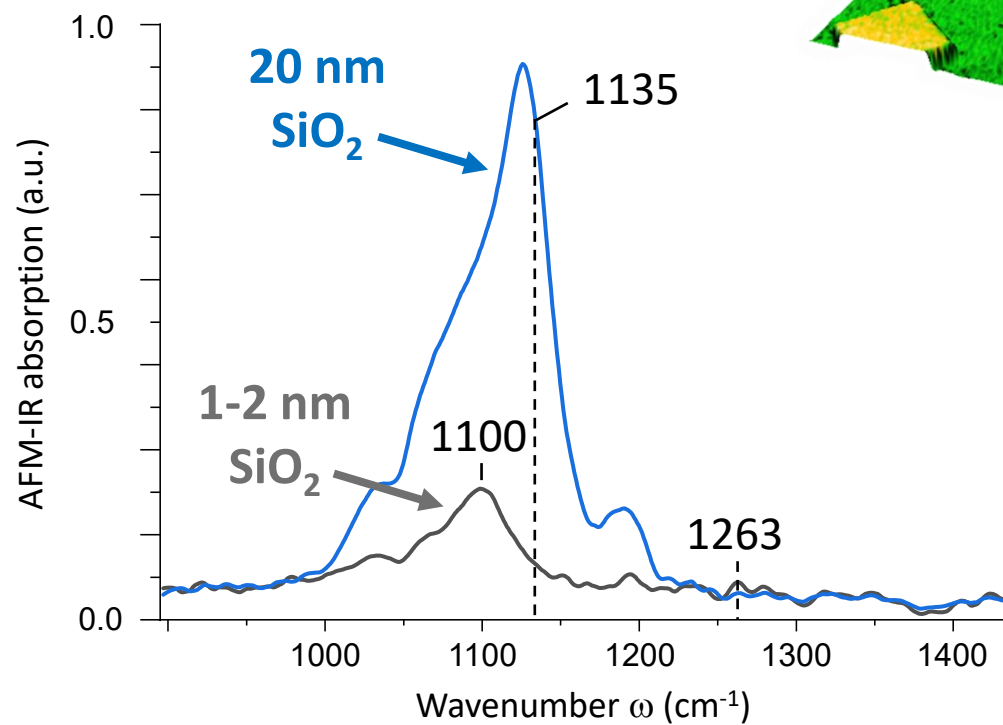
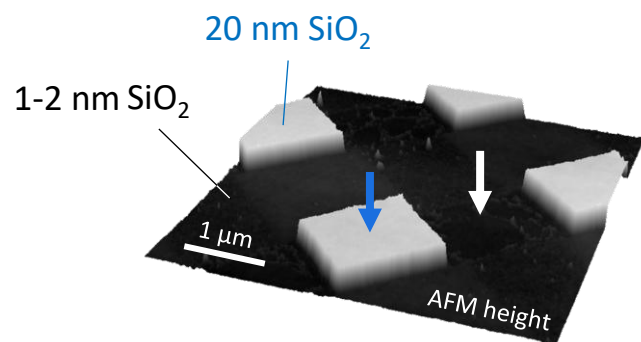


Resonant
(absorbing)



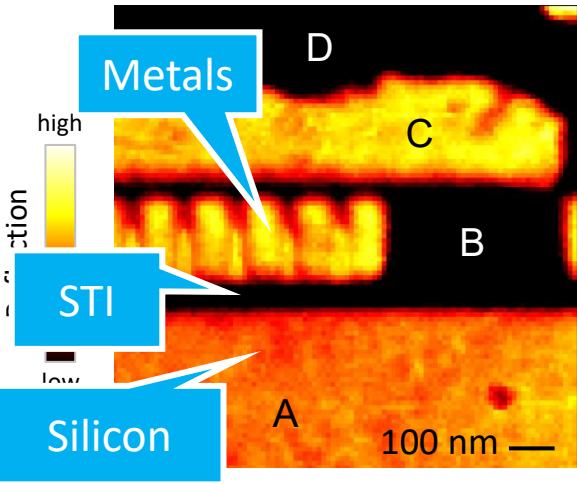
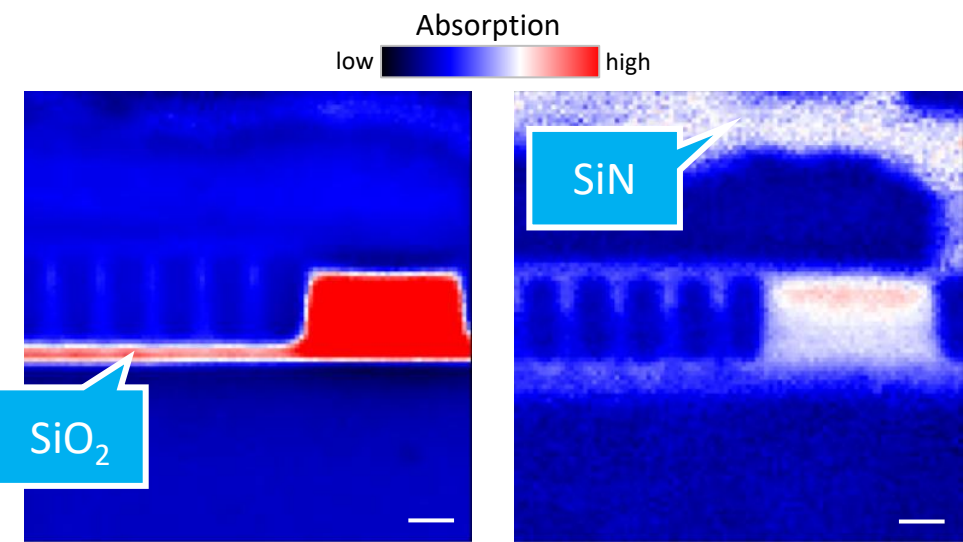
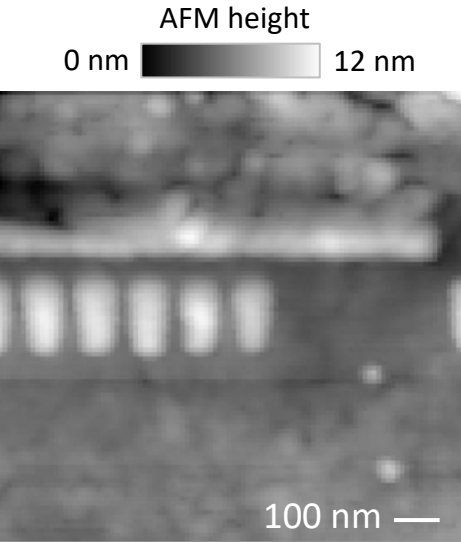
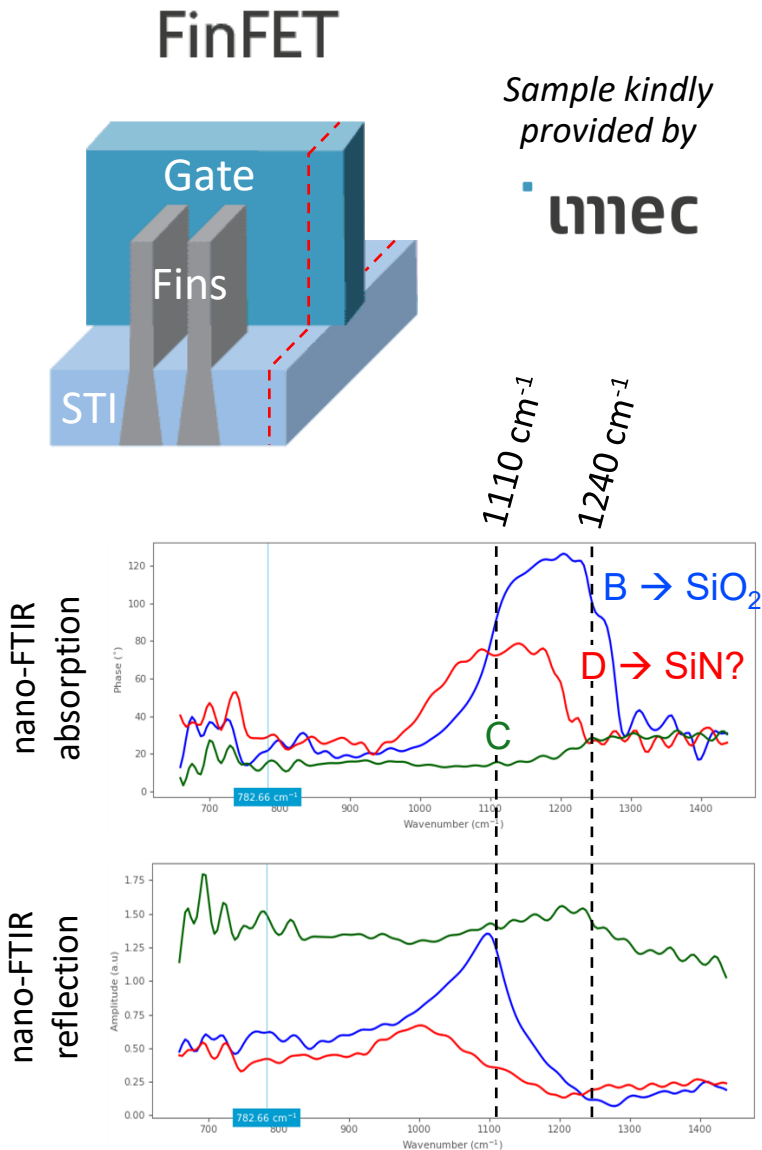
Characterization of thin films (oxides, nitrides, ...)

Attocube Tapping AFM-IR+ on calibration sample TGQ1

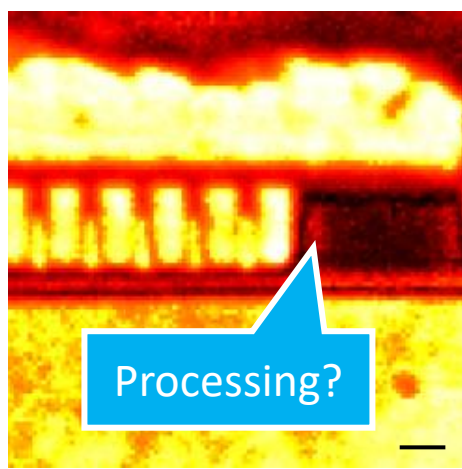


Preliminary nano-IR results on FinFET test structure

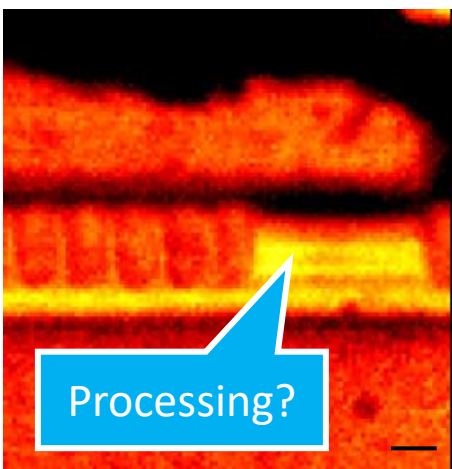
Cross-sectioned parallel to fin plane



1600 cm⁻¹
Reflection ≈ dielectric constant



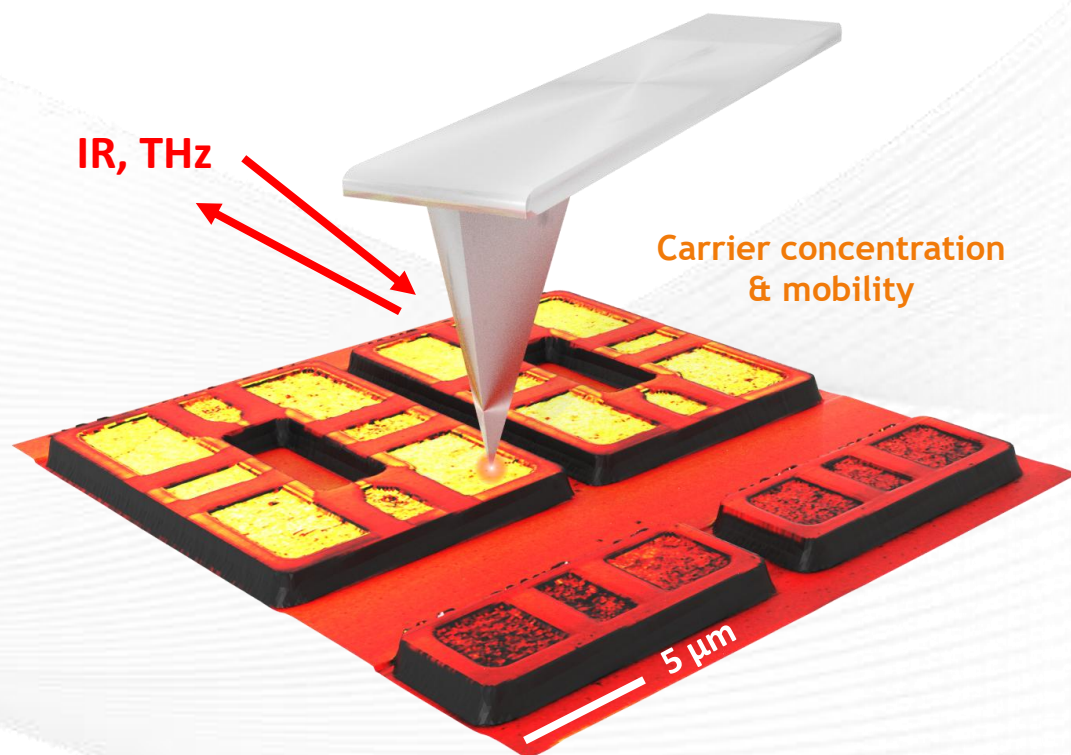
1240 cm⁻¹
SiO₂ absorbing
SiO₂ low reflection



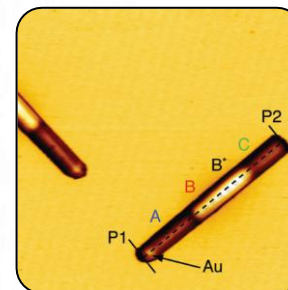
1110 cm⁻¹
SiN + SiO₂ both absorbing
SiO₂ high reflection

Optical probing of electrical properties

At infrared and terahertz frequencies

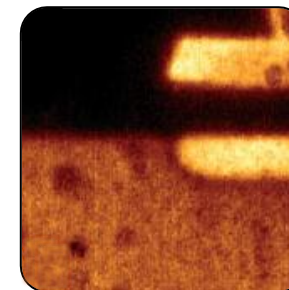


Nanowires



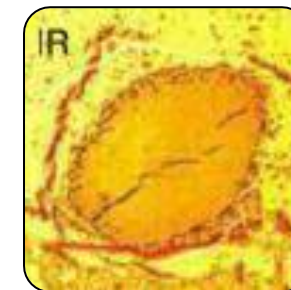
[J Stiegler \(2010\)](#)

Devices



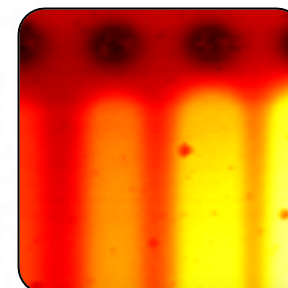
[A Huber \(2007\)](#)

2D organic conductors



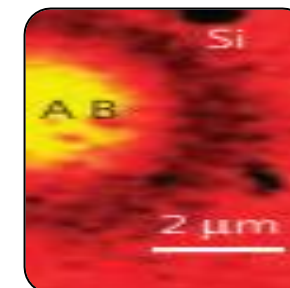
[T Zhang \(2025\)](#)

Dopant profiling



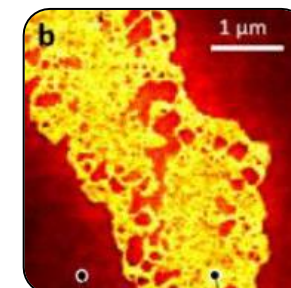
[C Liewald \(2018\)](#)

Carrier diffusion



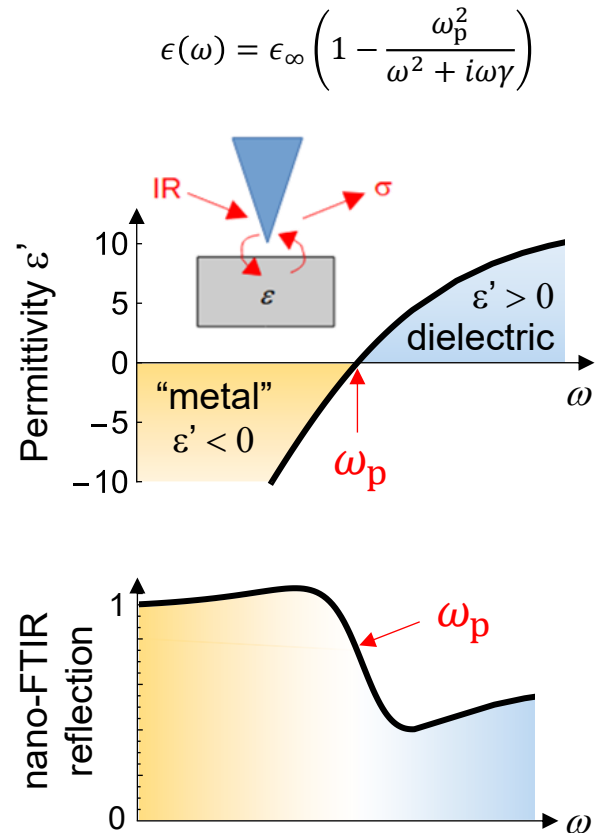
[F Huth \(2011\)](#)

Sub-surface conductivity



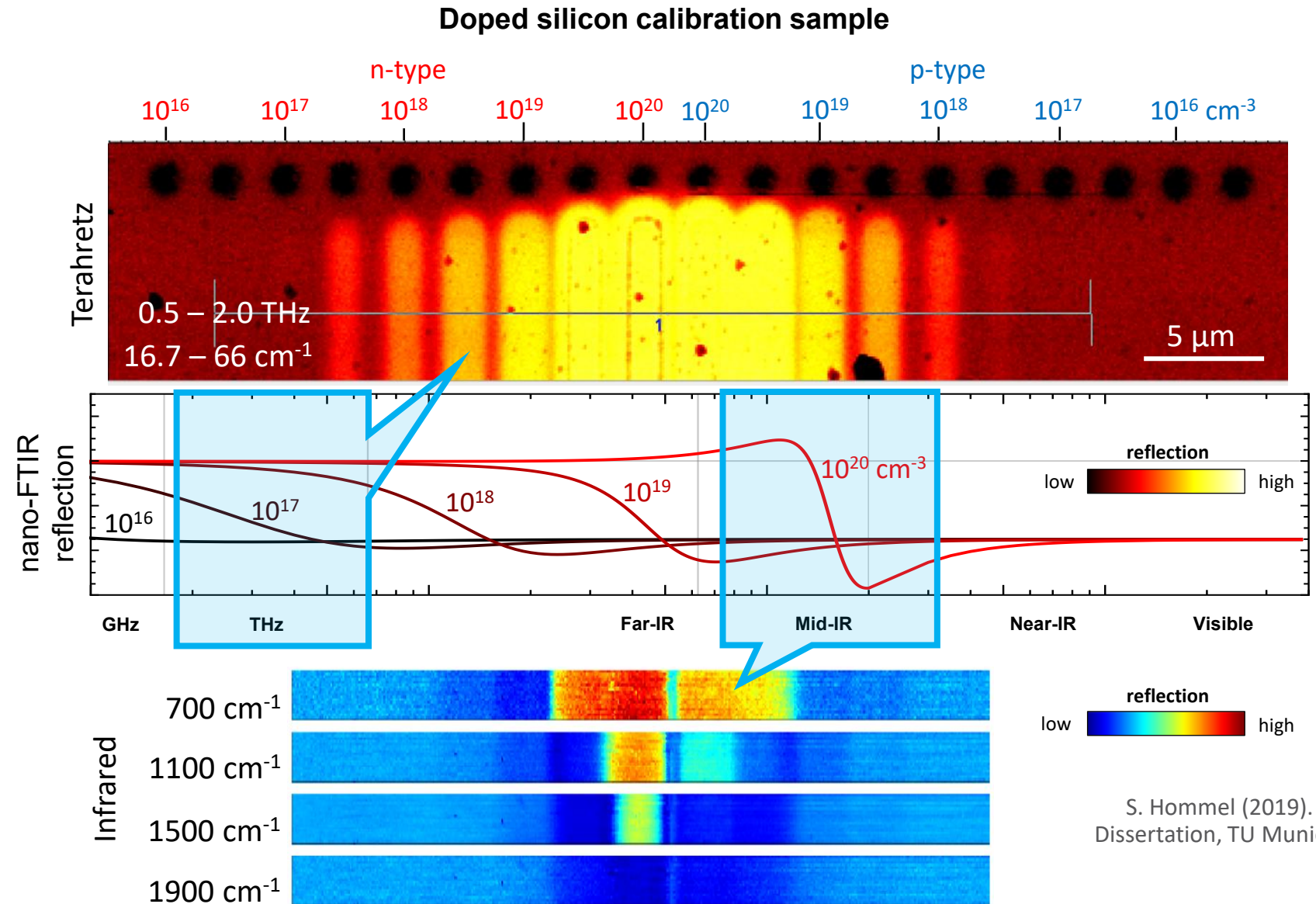
[M Sanviti \(2022\)](#)

Optical response (Drude model)



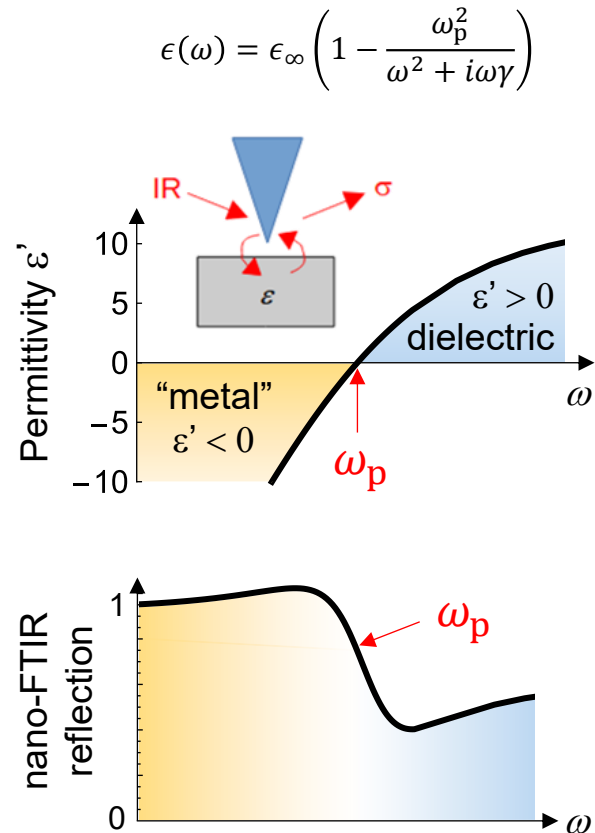
Plasma frequency: $\omega_p = \sqrt{\frac{ne^2}{\epsilon_{\infty}\epsilon_0 m^*}}$

=> n : Carrier concentration



S. Hommel (2019).
Dissertation, TU Munich.

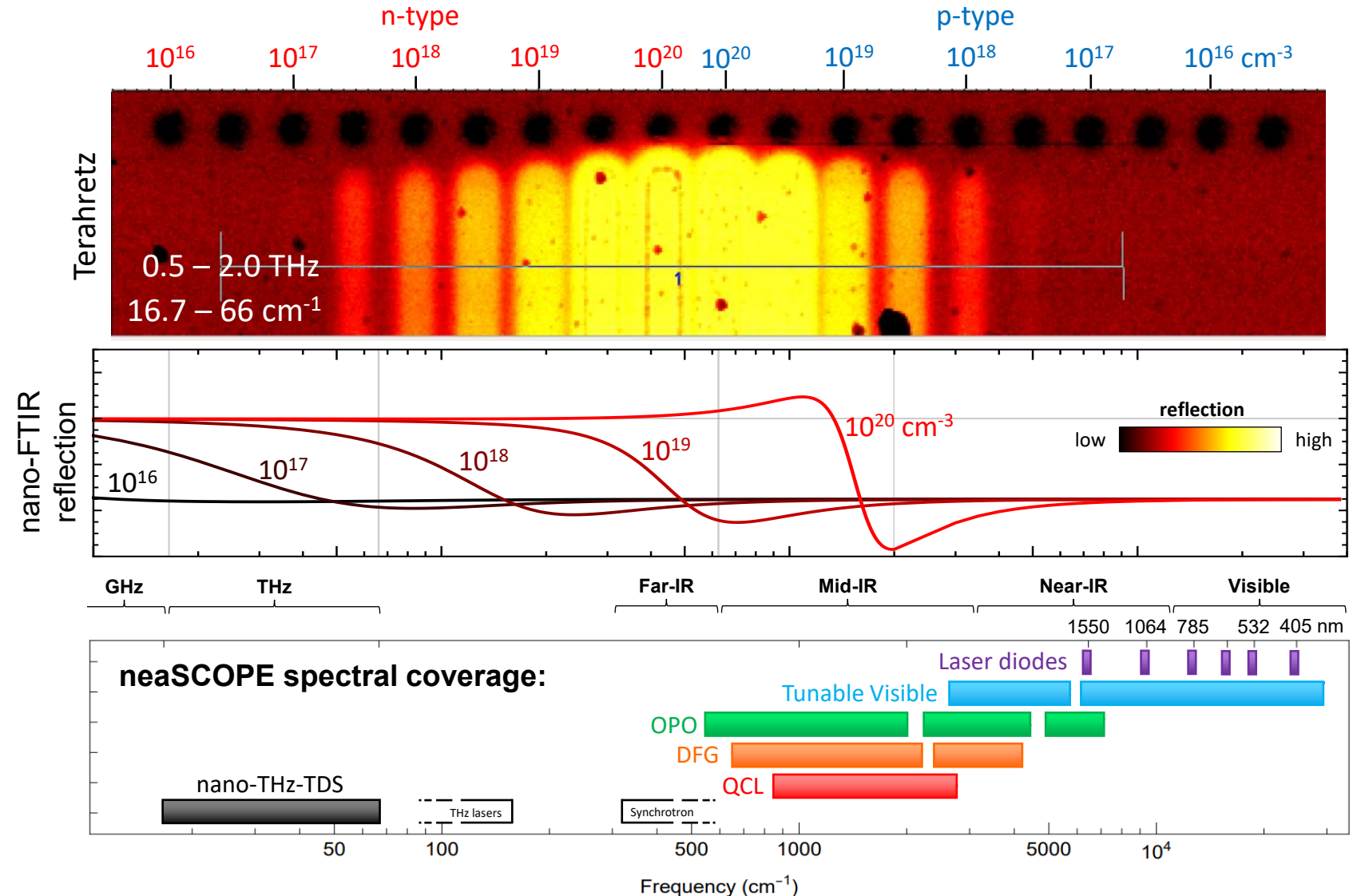
Optical response (Drude model)



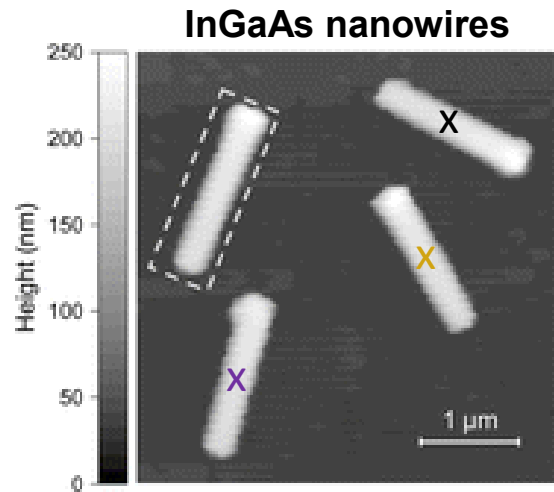
Plasma frequency: $\omega_p = \sqrt{\frac{ne^2}{\epsilon_{\infty}\epsilon_0 m^*}}$

=> n : Carrier concentration

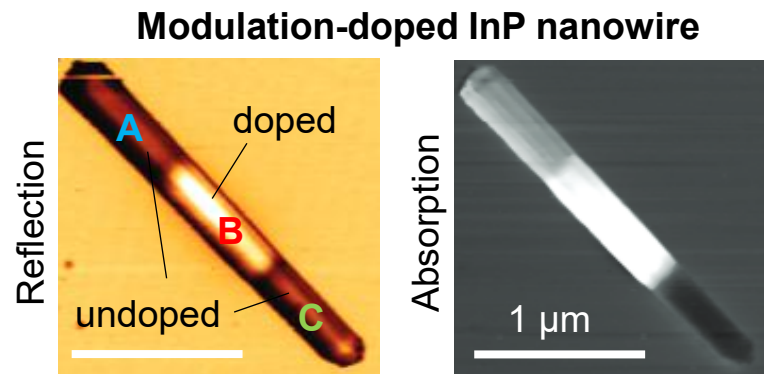
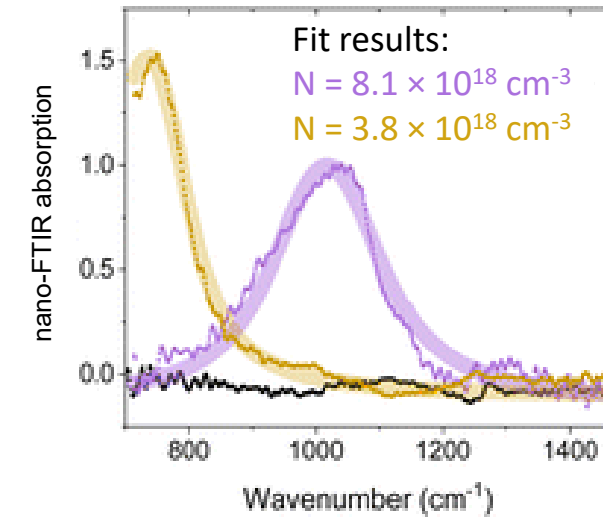
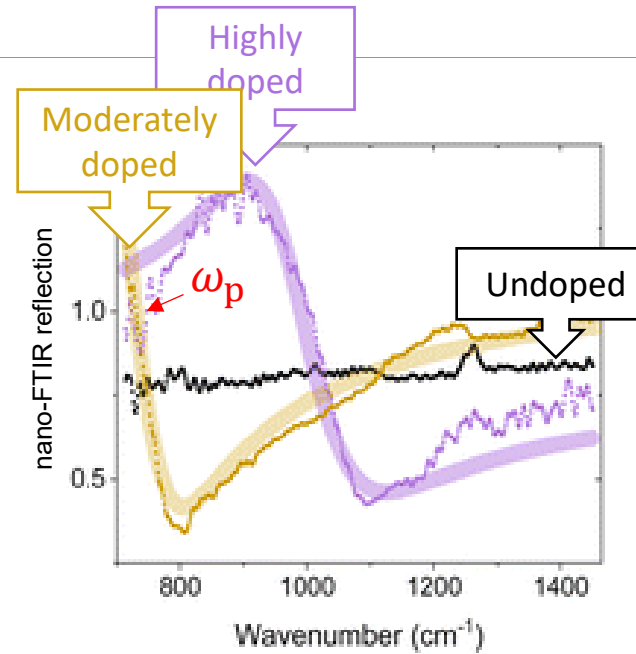
Doped silicon calibration sample



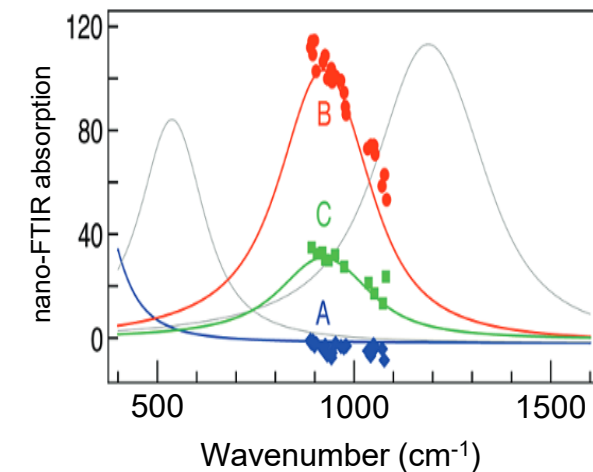
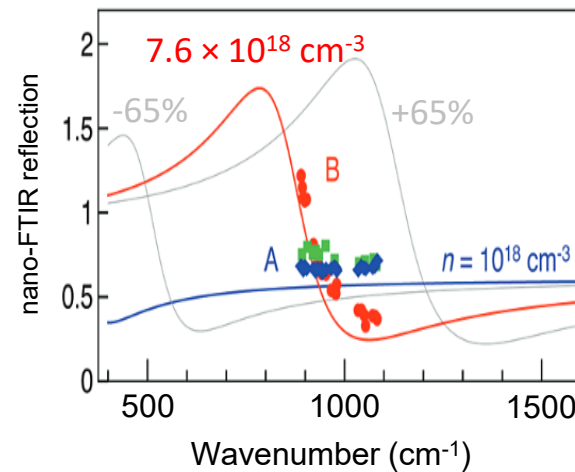
Nanoscale quantification of carrier concentration in individual nanowires



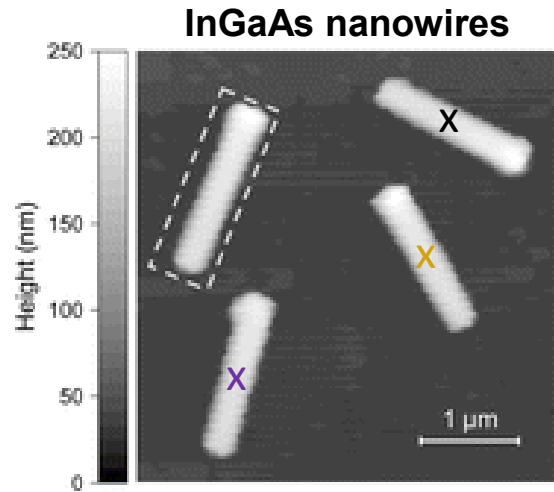
Luferau, *Nanoscale Adv.* **7**, 3692-3700 (2025)



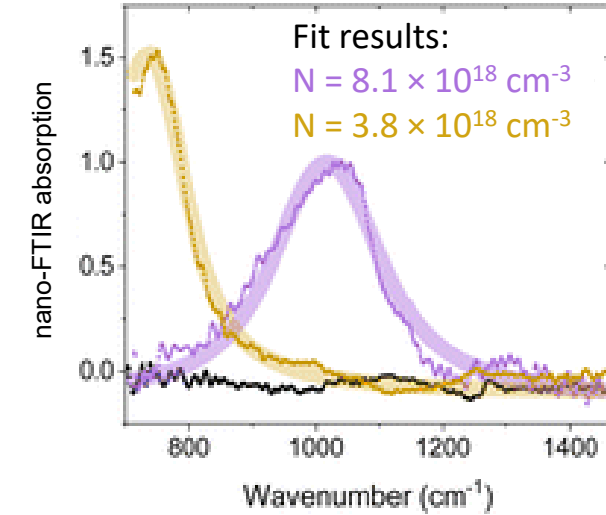
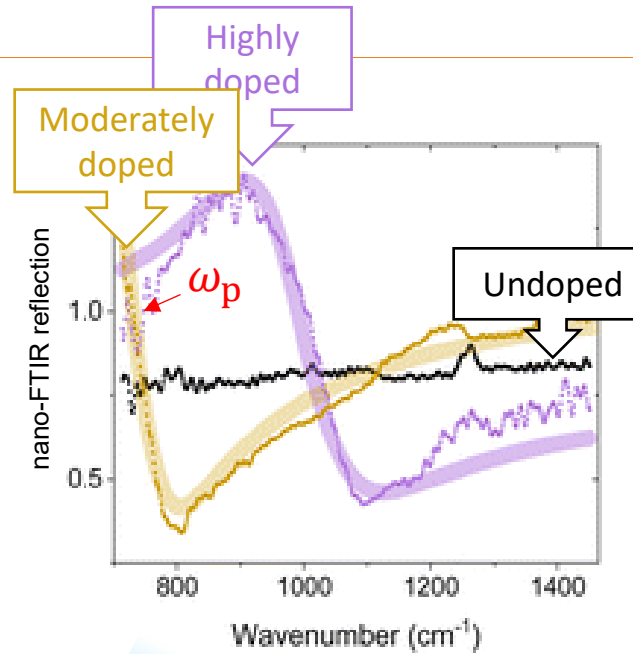
Stiegler, *Nano Lett.* **10**, 1387-1392 (2010)



Nanoscale quantification of carrier concentration in individual nanowires

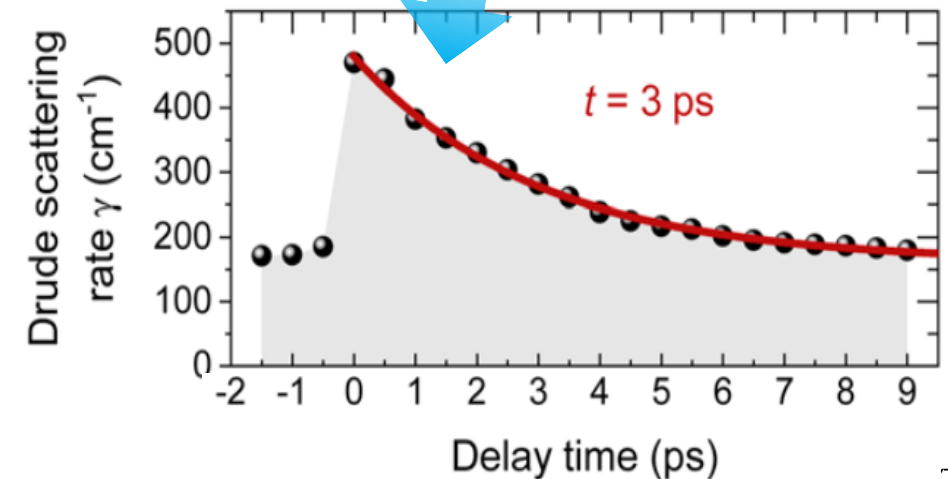
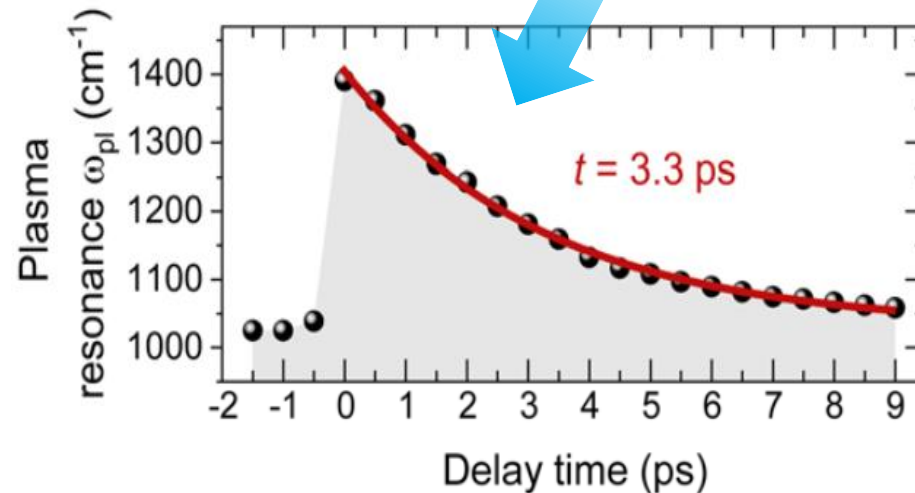


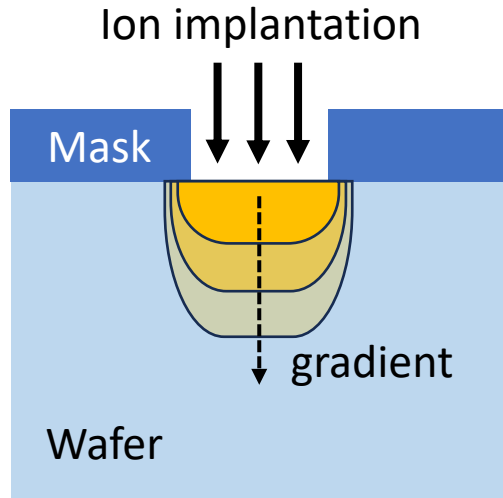
Luferau, *Nanoscale Adv.* **7**, 3692-3700 (2025)



Pump-probe nano-FTIR

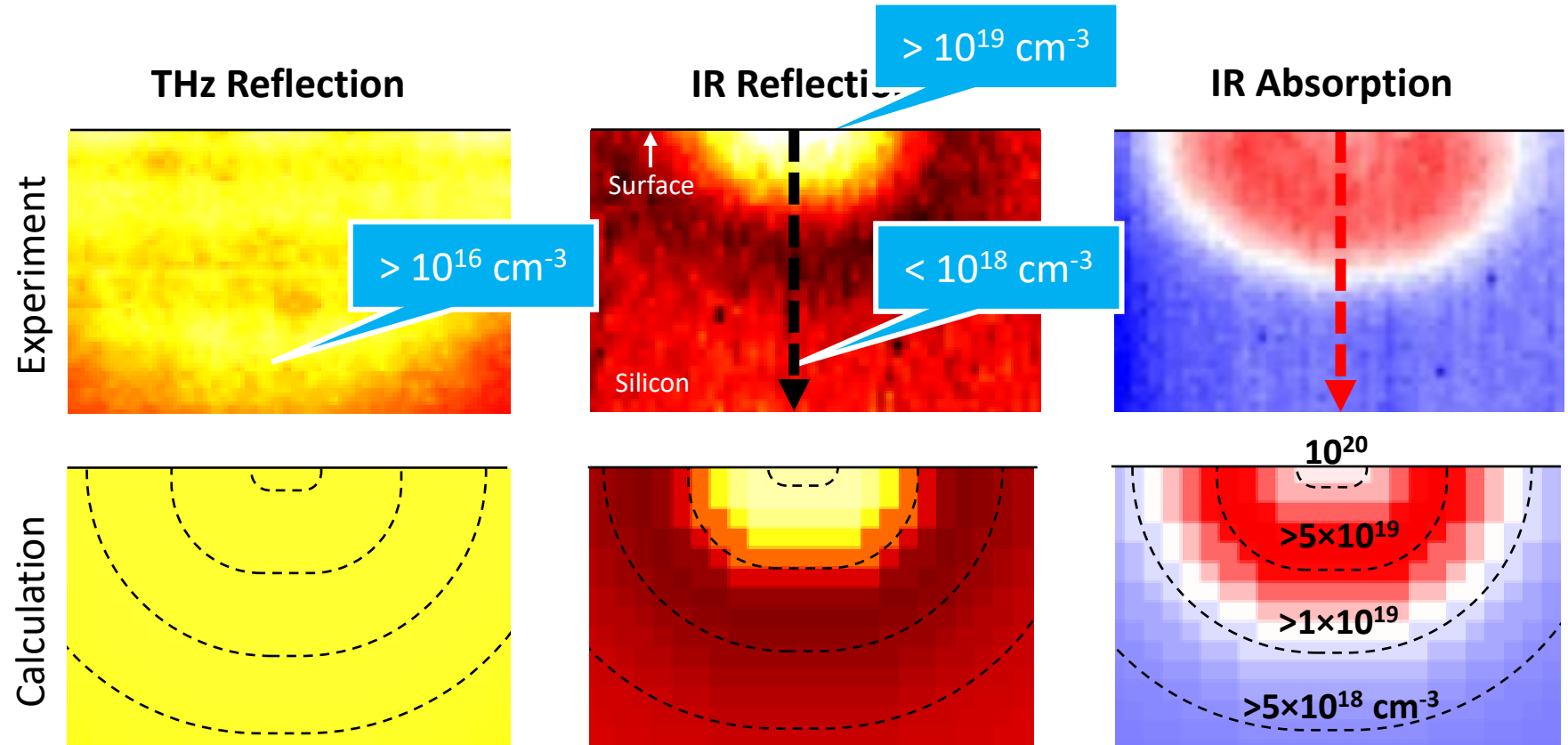
also at cryogenic temperatures,
also in vacuum





Sample cross-section

See also:
[Huth et al.,
Nature Mat. 10,
352-356 \(2011\)](#)



Order-of-magnitude-estimates of the carrier concentration:

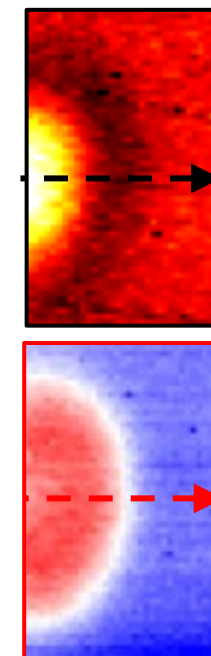
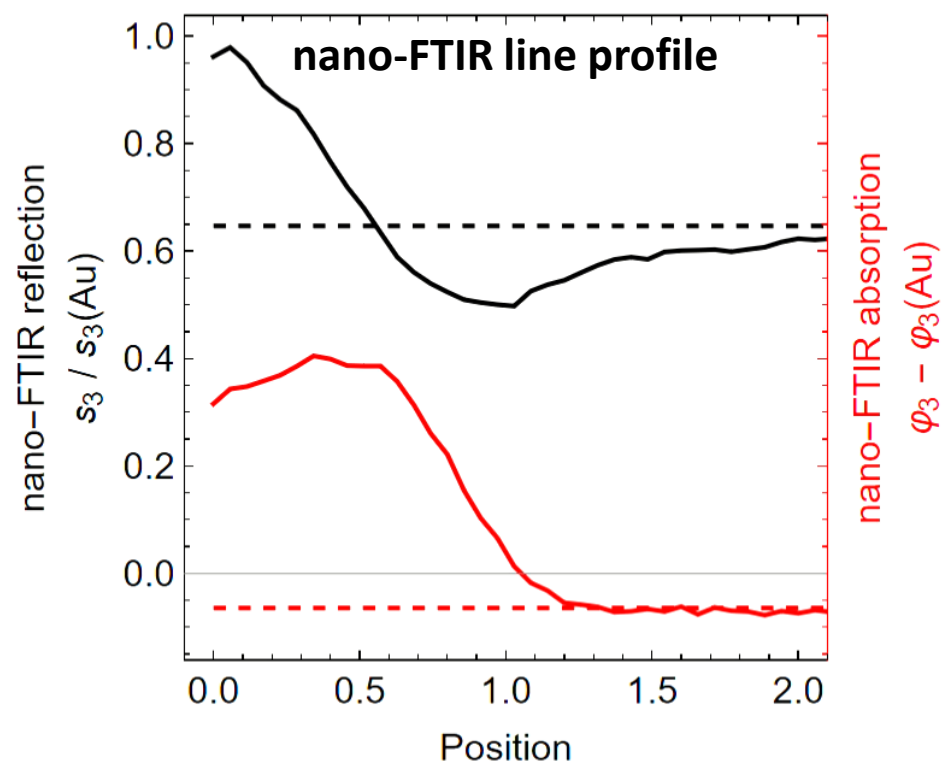
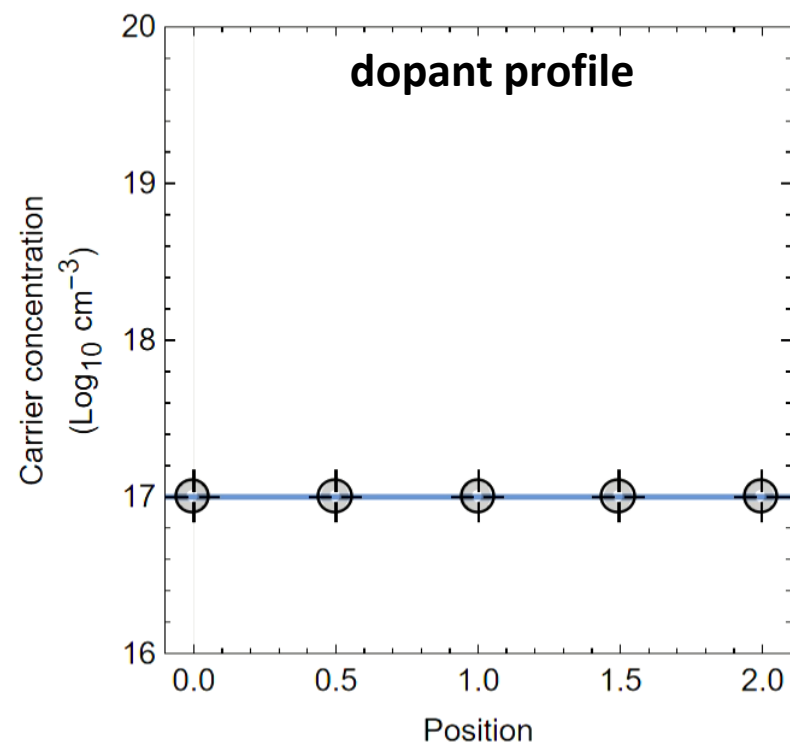
✓ (Electrical) Contact-free

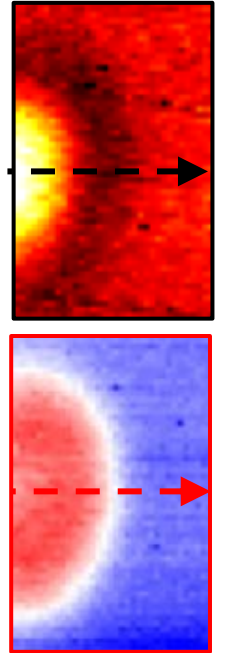
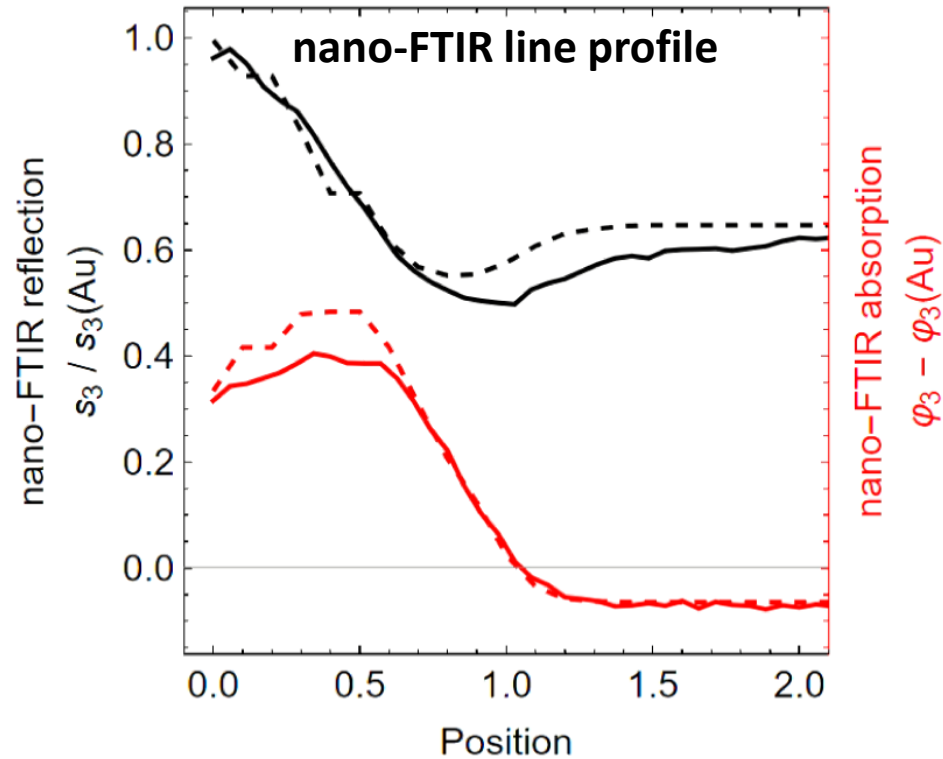
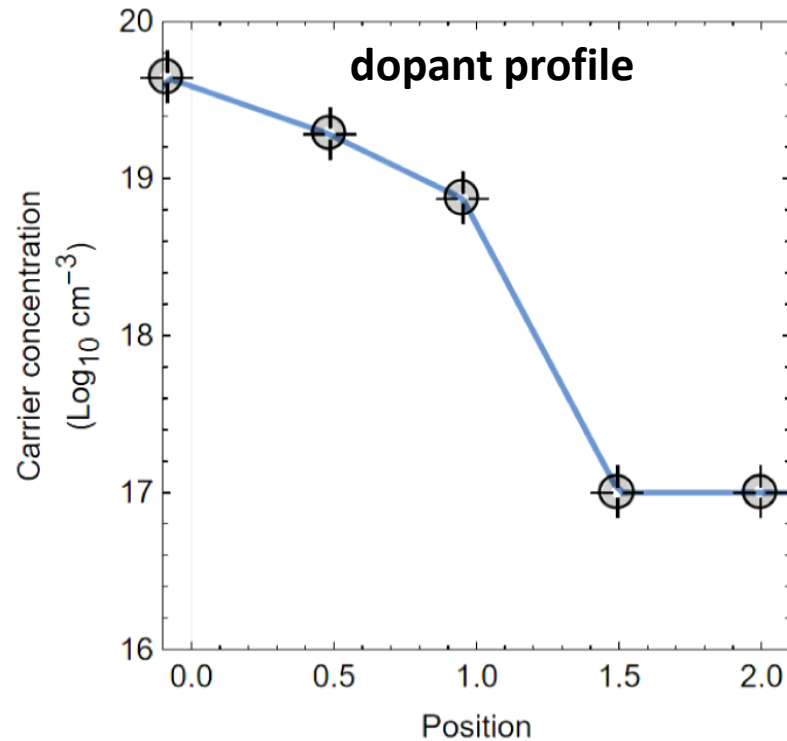
✓ Calibration-free

✓ (Mathematical) Model-free

✓ Non-destructive

...but we have models ☺





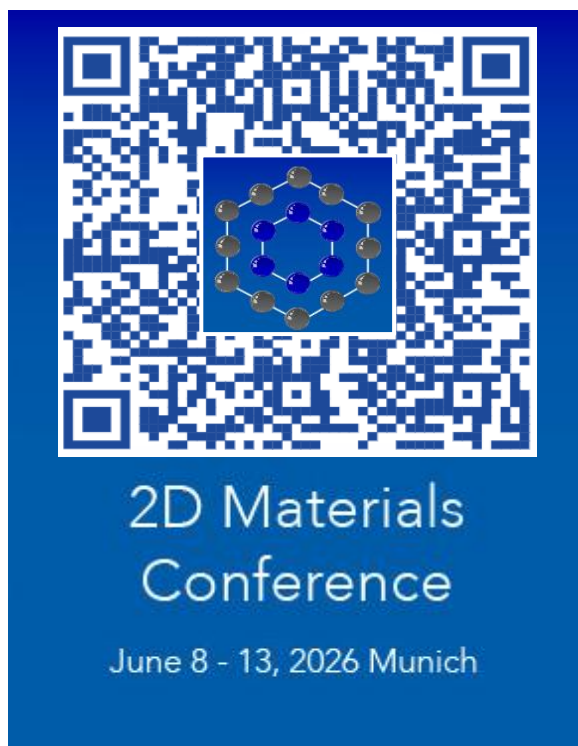
✓ High precision

✓ Subsurface-carrier profiling

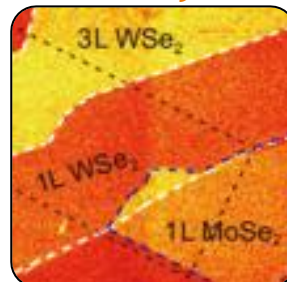
✓ Simultaneous electrical AFM

(✓) Detailed study on calibration sample missing

(✓) Lateral size-effects unexplored

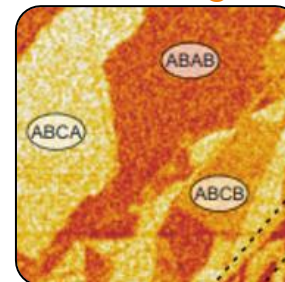


Monolayers



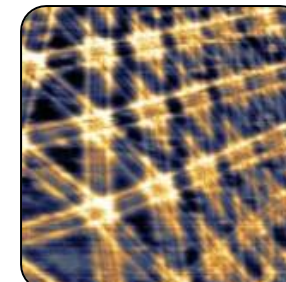
[S Zhang \(2022\)](#)

Stacking



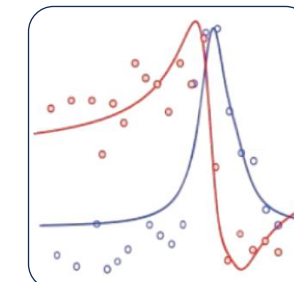
[K Wirth \(2022\)](#)

Moiré



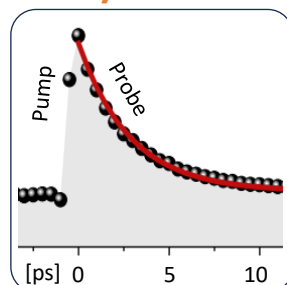
[Y Luo \(2020\)](#)

Excitons



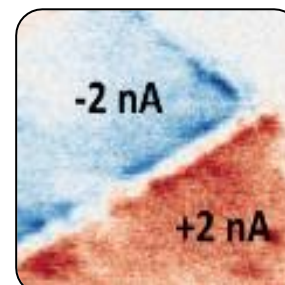
[S Zhang \(2022\)](#)

Dynamics



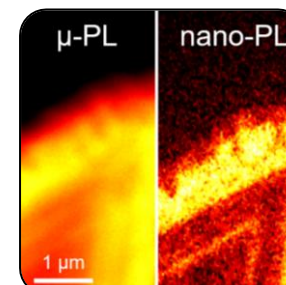
[A Luferau \(2025\)](#)

Photocurrent



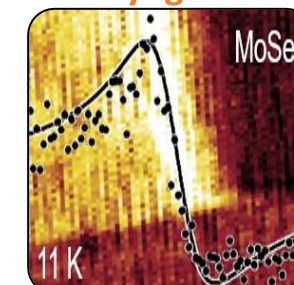
[attocube \(2023\)](#)

Nano-PL



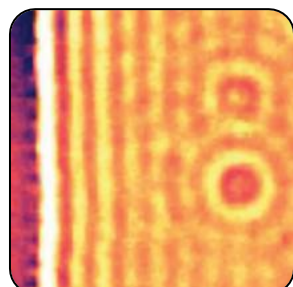
[attocube \(2025\)](#)

Cryogenic



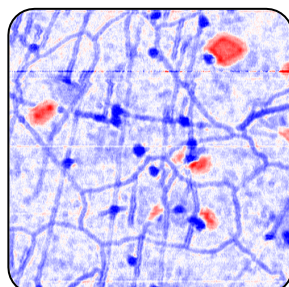
[A Roche \(2025\)](#)

Defects



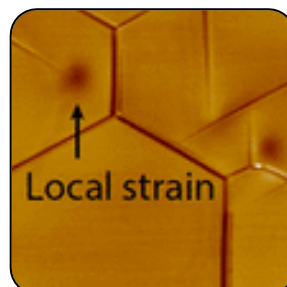
[D Rizzo \(2020\)](#)

Grain boundaries



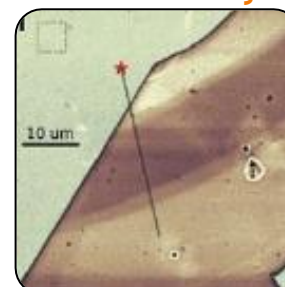
[M Schnell \(2020\)](#)

Strain



[B Lyu \(2019\)](#)

Conductivity



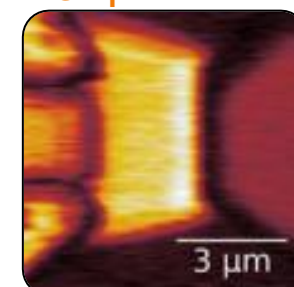
[H Lassen \(2023\)](#)

Intercalation



[J Pereira \(2022\)](#)

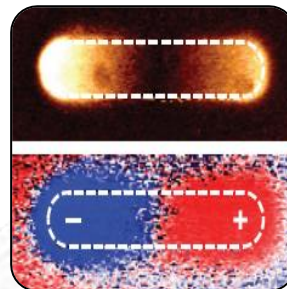
Graphene FET



[A Soltani \(2020\)](#)

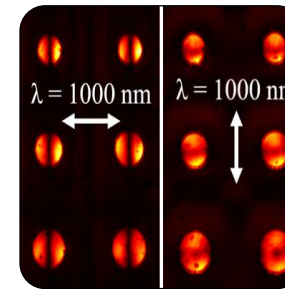


Plasmonics



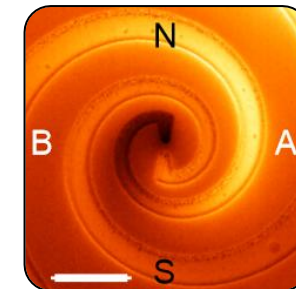
[M Schnell \(2010\)](#)

Polarization



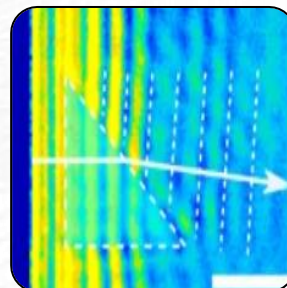
[V Zenin \(2017\)](#)

Resonators



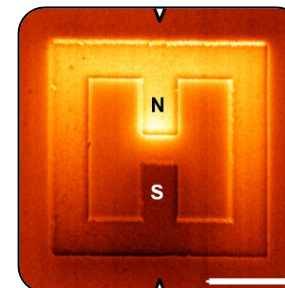
[L Thomas \(2022\)](#)

Wavefronts



[K Chaudhary \(2019\)](#)

Metamaterials



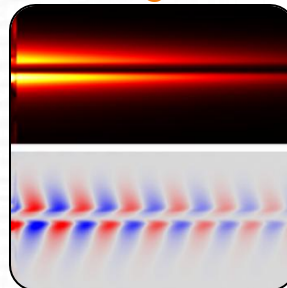
[L Thomas \(2022\)](#)

Photonic Crystals



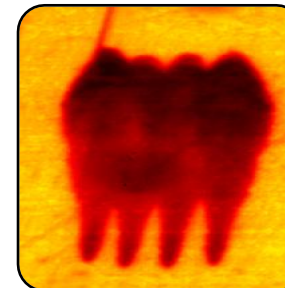
[F Alfaro-Mozaz \(2021\)](#)

Waveguides



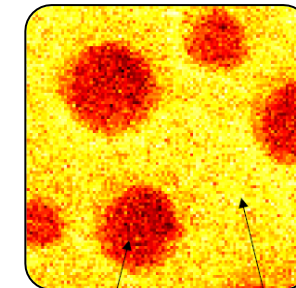
[A Andryieuski \(2014\)](#)

Densification



[N Shchedrina \(2024\)](#)

Refractive index



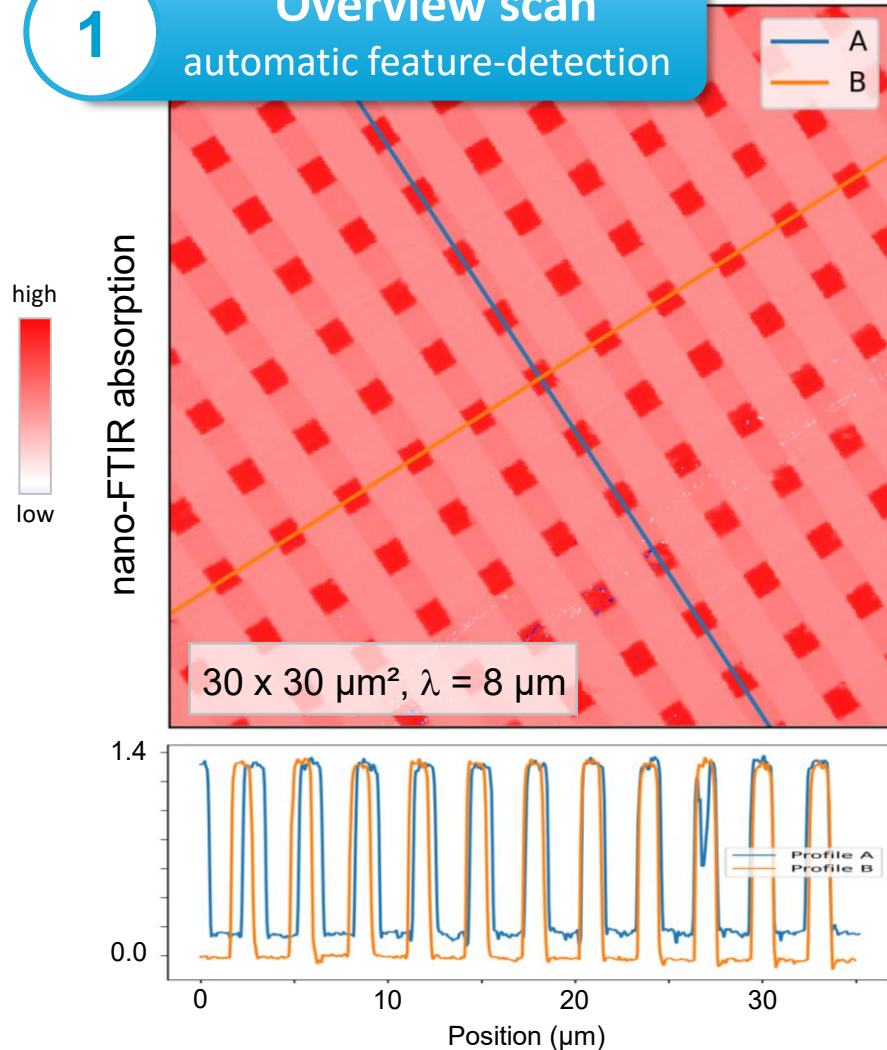
[attocube \(2025\)](#)

Full system automation is possible

Define measurement recipes “Storyboards” via expert mode “neaOSCI”, to run 1-click automated measurements & report

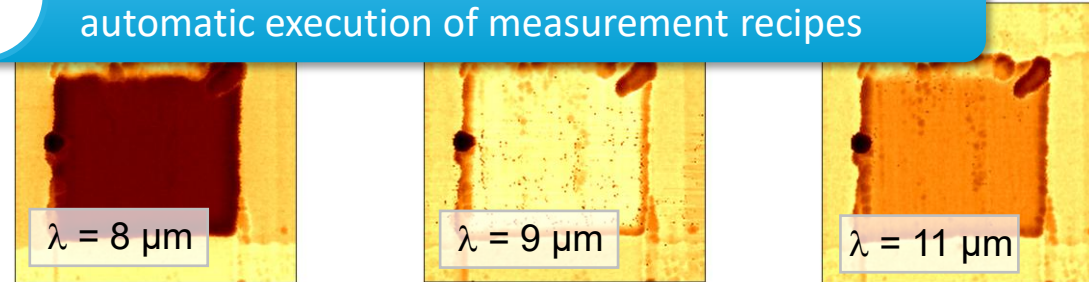
1

Overview scan automatic feature-detection



2

Zoom-in & spectroscopic imaging automatic execution of measurement recipes



3

Generate report automatic data analysis and print to PDF

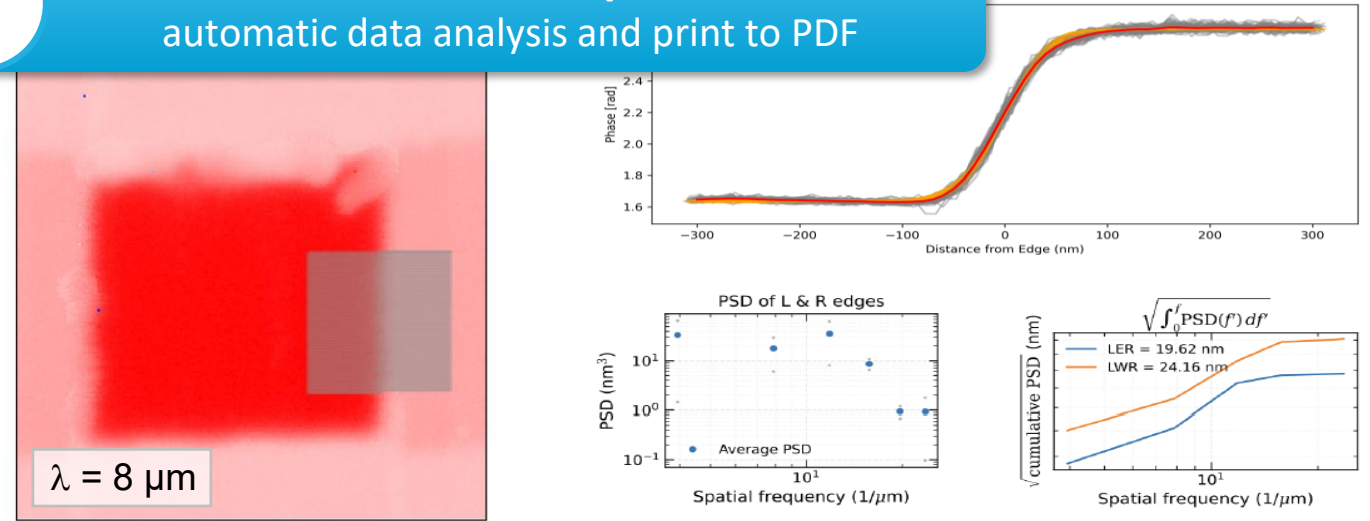


Figure 3. Power spectral density (PSD) analysis of line edges.

→ Talk to our automation experts!

neaSCOPE

pioneering nanospectroscopy solutions for all spectral ranges



All Tip-enhanced Optical Techniques

AFM-IR, nano-FTIR, s-SNOM, nano-Raman, nano-PL, nano-photocurrent at ambient & cryogenic conditions



Unmatched Spectral Coverage

From Visible to infrared to THz frequencies



Market-Leading Technology

Tailored for pioneering research & cutting-edge performance

IRa-SCOPE

routine infrared vibrational analysis at micro- & nano-scales



Correlative Nano-IR Capabilities

Combines nano-FTIR and AFM-IR imaging & spectroscopy for best performance on all sample types



Multidimensional Vibrational Spectroscopy

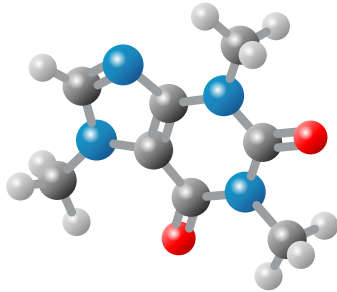
Integrates μ -IR, nano-IR and Raman with top-quality AFM



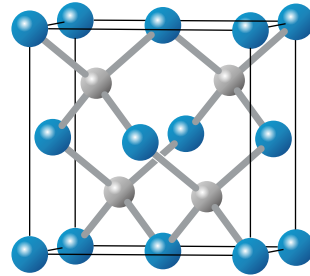
Reliability & Ease of Use

Sample-centric workflow, global coordinate system, instrument automation

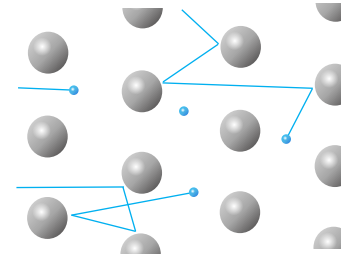
Molecular vibrations



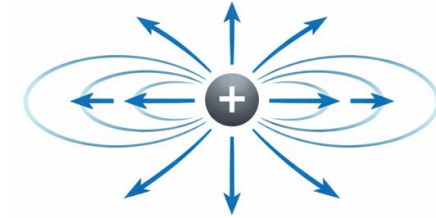
Lattice vibrations



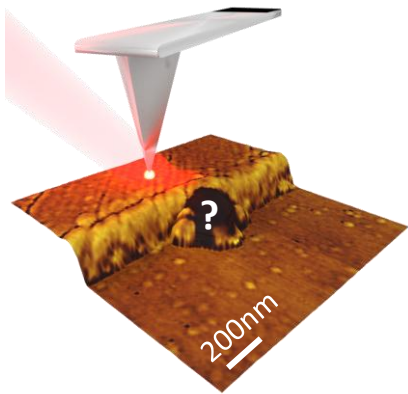
Charge carriers



Electric fields

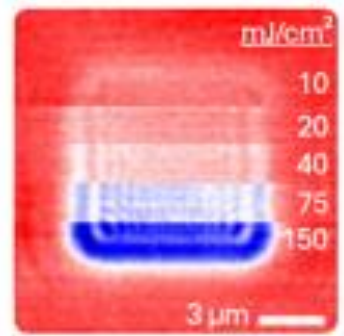


Contamination ID

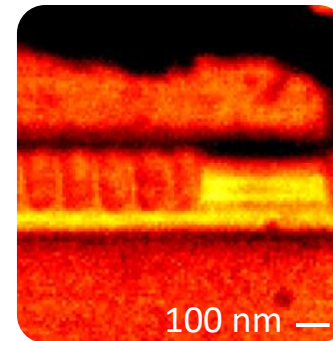


AFM-IR
Infrared

Lithography / Resists

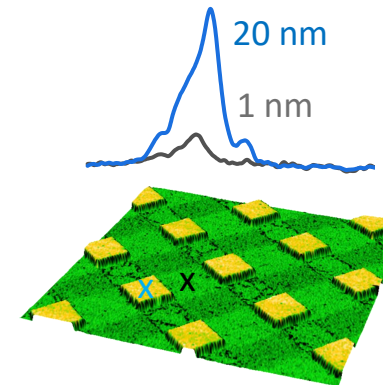


Dielectrics



nano-FTIR
Infrared, THz, Visible

Thin films



Dopant profiling

